



**THE DATASHEET OF  
PS32K144UAT0VLHA**



# S32K1XX

## S32K1xx Data Sheet

### Caution

- S32K148, S32K142, S32K146, and S32K116 specific information is preliminary until these devices are qualified.

### Key Features

- Operating characteristics
  - Voltage range: 2.7 V to 5.5 V
  - Ambient temperature range: -40 °C to 105 °C for HSRUN, -40 °C to 125 °C for RUN
- ARM™ Cortex-M4F/M0+ core, 32-bit CPU
  - Supports up to 112 MHz frequency (HSRUN) with 1.25 Dhrystone MIPS per MHz
  - ARM Core based on the ARMv7 Architecture and Thumb®-2 ISA
  - Integrated Digital Signal Processor (DSP)
  - Configurable Nested Vectored Interrupt Controller (NVIC)
  - Single Precision Floating Point Unit (FPU)
- Clock interfaces
  - 4 - 40 MHz fast external oscillator (SOSC)
  - 48 MHz Fast Internal RC oscillator (FIRC)
  - 8 MHz Slow Internal RC oscillator (SIRC)
  - 128 kHz Low Power Oscillator (LPO)
  - Up to 112 MHz (HSRUN) System Phased Lock Loop (SPLL)
  - Up to 50 MHz DC external square wave input clock
  - Real Time Counter (RTC)
- Power management
  - Low-power ARM Cortex-M4F/M0+ core with excellent energy efficiency
  - Power Management Controller (PMC) with multiple power modes: HSRUN, Run, Stop, VLPR, and VLPS
  - Supports peripheral specific clock gating. Only specific peripherals remain working in low power modes.
- Memory and memory interfaces
  - Up to 2 MB program flash memory with ECC
  - 64 KB FlexNVM for data flash memory with ECC and EEPROM emulation
  - Up to 256 KB SRAM with ECC
  - Up to 4 KB of FlexRAM for use as SRAM or EEPROM emulation
  - Up to 4 KB Code cache to minimize performance impact of memory access latencies
  - QuadSPI with HyperBus™ support
- Mixed-signal analog
  - Up to two 12-bit Analog-to-Digital Converter (ADC) with up to 32 channel analog inputs per module
  - One Analog Comparator (CMP) with internal 8-bit Digital to Analog Converter (DAC)
- Debug functionality
  - Serial Wire JTAG Debug Port (SWJ-DP) combines
  - Debug Watchpoint and Trace (DWT)
  - Instrumentation Trace Macrocell (ITM)
  - Test Port Interface Unit (TPIU)
  - Flash Patch and Breakpoint (FPB) Unit
- Human-machine interface (HMI)
  - Up to 156 GPIO pins with interrupt functionality
  - Non-Maskable Interrupt (NMI)
- Communications interfaces
  - Up to three Low Power Universal Asynchronous Receiver/Transmitter (LPUART) modules with DMA support and low power availability
  - Up to three Low Power Serial Peripheral Interface (LPSPI) modules with DMA support and low power availability
  - Up to two Low Power Inter-Integrated Circuit (LPI2C) modules with DMA support and low power availability
  - Up to three FlexCAN modules (with optional CAN-FD support)
  - FlexIO module for flexible and high performance serial interfaces

This document contains information on a product under development. NXP reserves the right to change or discontinue this product without notice.

Preliminary



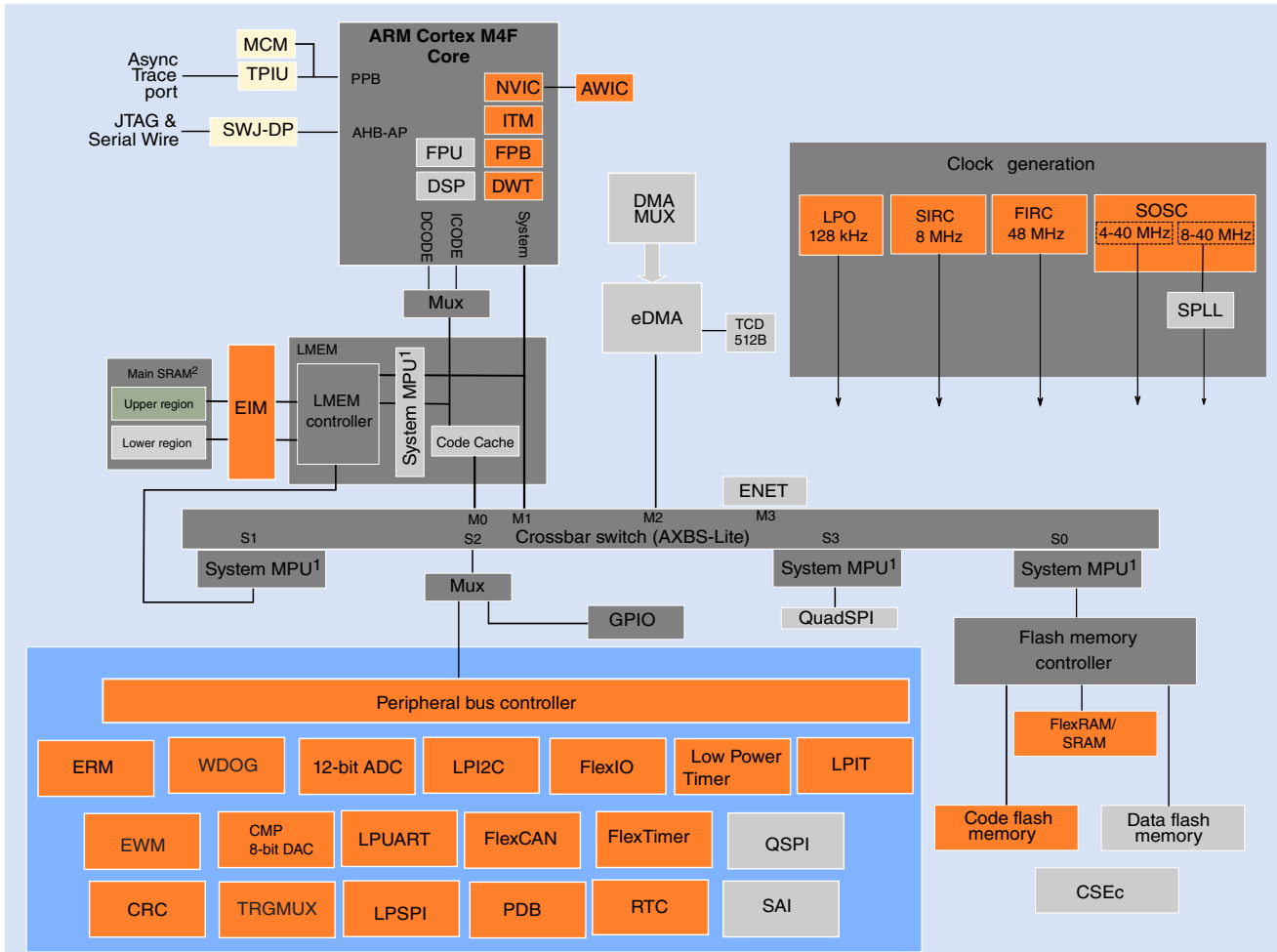
- Reliability, safety and security
  - HW Security Engine (CSEc)
  - Internal watchdog (WDOG)
  - External Watchdog monitor (EWM) module
  - Error-Correcting Code (ECC) on flash and SRAM memories
  - Cyclic Redundancy Check (CRC) module
  - 128-bit Unique Identification (ID) number
  - System Memory Protection Unit (System MPU)
- Timing and control
  - Up eight independent 16-bit FlexTimers (FTM) module, offering up to 64 standard channels (IC/OC/PWM)
  - One 16-bit Low Power Timer (LPTMR) with flexible wake up control
  - Two Programmable Delay Blocks (PDB) with flexible trigger system
  - One 32-bit Low Power Interrupt Timer (LPIT) with 4 channels
  - 32-bit Real Time Counter (RTC)
- I/O and package
  - 32-pin QFN, 48-pin LQFP, 64-pin LQFP, 100-pin LQFP, MAPBGA-100, 144-pin LQFP, 176-pin LQFP package options
- 16 channel DMA with up to 63 request sources using DMAMUX

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# 1 Block diagram

Following figures show superset high level architecture block diagrams of S32K14x series and S32K11x series respectively. Other devices within the family have a subset of the features. See [Feature comparison](#) for chip specific values.

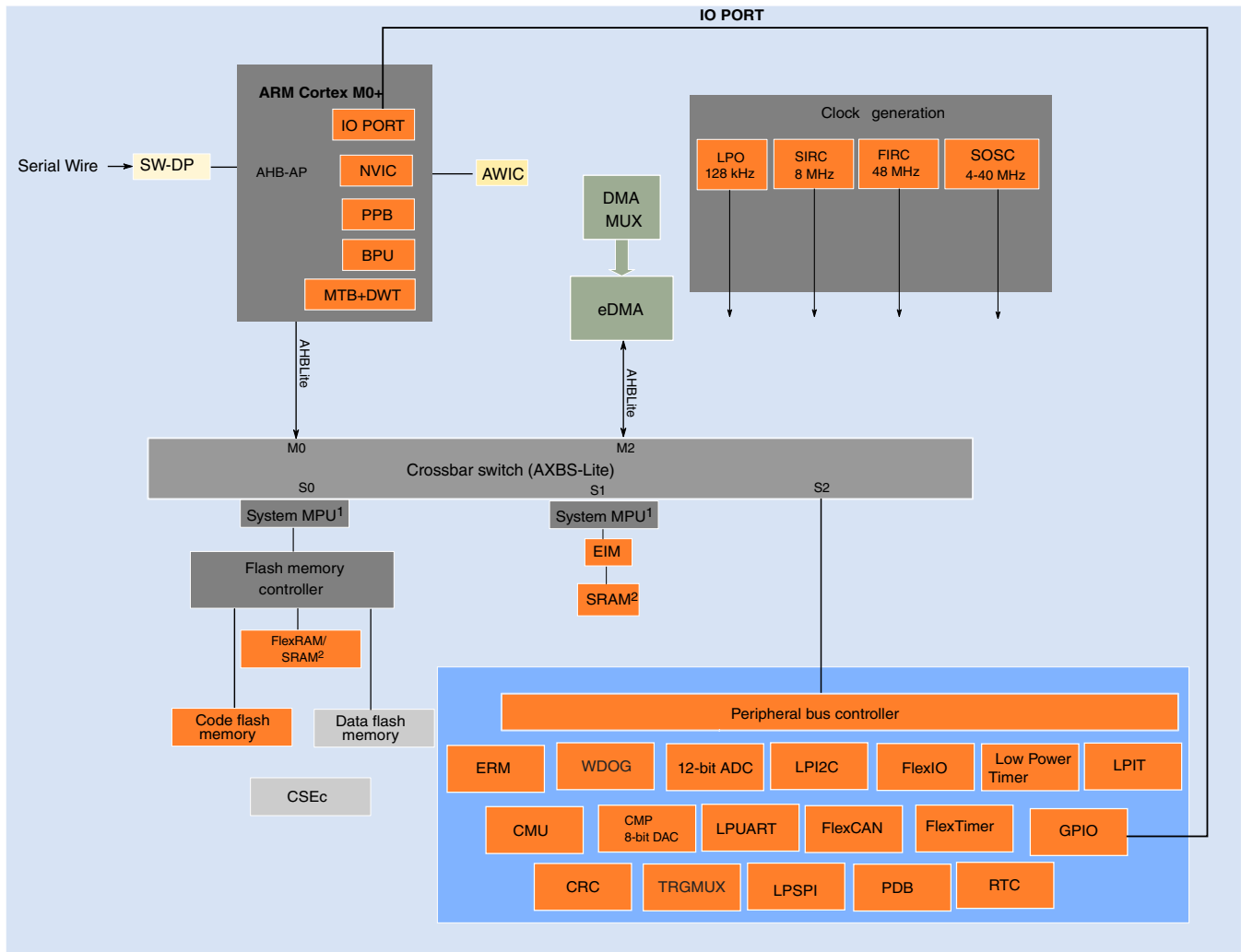


1: On this device, NXP's system MPU implements the safety mechanisms to prevent masters from accessing restricted memory regions. This system MPU provides memory protection at the level of the Crossbar Switch. Each Crossbar master (Core, DMA, Ethernet) can be assigned different access rights to each protected memory region. The ARM M4 core version in this family does not integrate the ARM Core MPU, which would concurrently monitor only core-initiated memory accesses. In this document, the term MPU refers to NXP's system MPU.

2: For the device-specific sizes, see the "On-chip SRAM sizes" table in the "Memories and Memory Interfaces" chapter of the S32K14x Series Reference Manual.

Key:	Device architectural IP on all S32K devices
	Peripherals present on all S32K devices
	Peripherals present on selected S32K devices (see the "Feature Comparison" section in the RM)

**Figure 1. High-level architecture diagram for the S32K14x family**



1: On this device, NXP's system MPU implements the safety mechanisms to prevent masters from accessing restricted memory regions. This system MPU provides memory protection at the level of the Crossbar Switch. Crossbar master (Core, DMA) can be assigned different access rights to each protected memory region. The ARM M0+ core version in this family does not integrate the ARM Core MPU, which would concurrently monitor only core-initiated memory accesses. In this document, the term MPU refers to NXP's system MPU.

2: For the device-specific sizes, see the "On-chip SRAM sizes" table in the "Memories and Memory Interfaces" chapter of the S32K1xx Series Reference Manual.

Device architectural IP on all S32K devices
Peripherals present on all S32K devices
Peripherals present on selected S32K devices (see the "Feature Comparison" section in the RM)

Figure 2. High-level architecture diagram for the S32K11x family

## 2 Feature comparison

The following figure summarizes the memory and package options for the S32K product series and demonstrates where this device fits within the overall series. All devices which share a common package are pin-to-pin compatible.

## Feature comparison

		S32K11x		S32K14x			
Parameter		K116	K118	K142	K144	K146	K148
System	Core	ARM® Cortex™-M0+		ARM® Cortex™-M4F			
	Frequency	48 MHz		up to 112 MHz (HSRUN)			
	IEEE-754 FPU	○		●			
	HW security module (CSEc) <sup>1</sup>	●		●			
	CRC module	1x		1x			
	ISO 26262	capable up to ASIL-B		capable up to ASIL-B			
	Peripheral speed	up to 48 MHz		up to 112 MHz (HSRUN)			
	Crossbar	●		●			
	DMA	●		●			
	EWM	○		●			
	Memory protection unit	●		●			
	FIRC CMU	●		○			
	Watchdog	1x		1x			
	Low power modes	●		●			
	HSRUN mode	○		●			
	Number of I/Os	up to 43	up to 58	up to 89	up to 128	up to 156	
	Single supply voltage	2.7 - 5.5 V		2.7 - 5.5 V			
Operating temperature (T <sub>a</sub> ) Temperature ambient	-40 to +85°C / +105°C / +125°C		-40 to +85°C / +105°C / +125°C				
Memory	Flash	128 KB	256 KB	256 KB	512 KB	1 MB	2 MB <sup>2</sup>
	Error correction code (ECC)	●		●			
	System RAM (including FlexRAM and MTB)	17 KB	25 KB	32 KB	64 KB	128 KB	256 KB
	FlexRAM (also available as system RAM)	2 KB		4 KB			
	Cache	○		4 KB			
	EEPROM emulated by FlexRAM <sup>1</sup>	2 KB (up to 32 KB D-Flash)		4 KB (up to 64 KB D-Flash)			4 KB (up to 512 KB D-Flash as a part of 2 MB Flash) <sup>3</sup>
	External memory interface	○		○			QuadSPI incl. HyperBus™
Timer	Low power interrupt timer	1x		1x			
	FlexTimer (16-bit counter) 8 channels	2x (16)		4x (32)		6x (48)	8x (64)
	Low power timer (LPTMR)	1x		1x			
	Real time counter (RTC)	1x		1x			
	Programmable delay block (PDB)	1x		2x			
Analog	Trigger mux (TRGMUX)	1x (43)	1x (45)	1x (64)		1x (73)	1x (81)
	12-bit SAR ADC (1 MSPS each)	1x (14)	1x (16)	2x (16)		2x (24)	2x (32)
	Comparator with 8-bit DAC	1x		1x			
Communication	100 Mbit IEEE-1588 ethernet MAC	○		○		1x	
	Serial audio interface (AC97, TDM, I2S)	○		○		2x	
	Low power UART/LIN (Supports LIN protocol versions 1.3, 2.0, 2.1, and SAE J2602)	2x		2x	3x		
	Low power SPI	1x	2x	2x	3x		
	Low power I2C	1x		1x			2x
	FlexCAN (CAN-FD ISO/CD 11898-1)	1x (1x with FD)	1x (1x with FD)	2x (1x with FD)	3x (1x with FD)	3x (2x with FD)	3x (3x with FD)
IDEs	FlexIO (8 pins configurable as UART, SPI, I2C, I2S)	1x		1x			
	Debug & trace	SWD, MTB (1 KB), JTAG <sup>4</sup>		SWD, JTAG (ITM, SWV, SWO)			SWD, JTAG (ITM, SWV, SWO), ETM
Other	Ecosystem (IDE, compiler, debugger)	NXP S32 Design Studio (GCC) + SDK, IAR, GHS, COSMIC, Lauterbach, iSystems		NXP S32 Design Studio (GCC) + SDK, IAR, GHS, COSMIC, Lauterbach, iSystems			
	Packages	QFN-32 LQFP-48	LQFP-48 LQFP-64	LQFP-64 LQFP-100	LQFP-64 LQFP-100 MAPBGA-100	LQFP-64 MAPBGA-100 LQFP-100 LQFP-144	MAPBGA-100 LQFP-144 LQFP-176

### LEGEND:

- Not implemented
- Available on the device
- <sup>1</sup> No FTFC commands, including CSE commands (CSEc parts) are available when chip is in VLPR or HSRUN mode.
- <sup>2</sup> Available when EEPROM, CSEc and Data Flash are not used. Else only up to 1,984 KB is available for Program Flash.
- <sup>3</sup> Up to 64 KB of flash is used as EEPROM backup and the remaining 448 KB of the last 512 KB block can be used as Data flash or Program flash. See chapter FTFC for details.
- <sup>4</sup> Only for BSR

**Figure 3. S32K1xx product series comparison**

## 3 Ordering parts

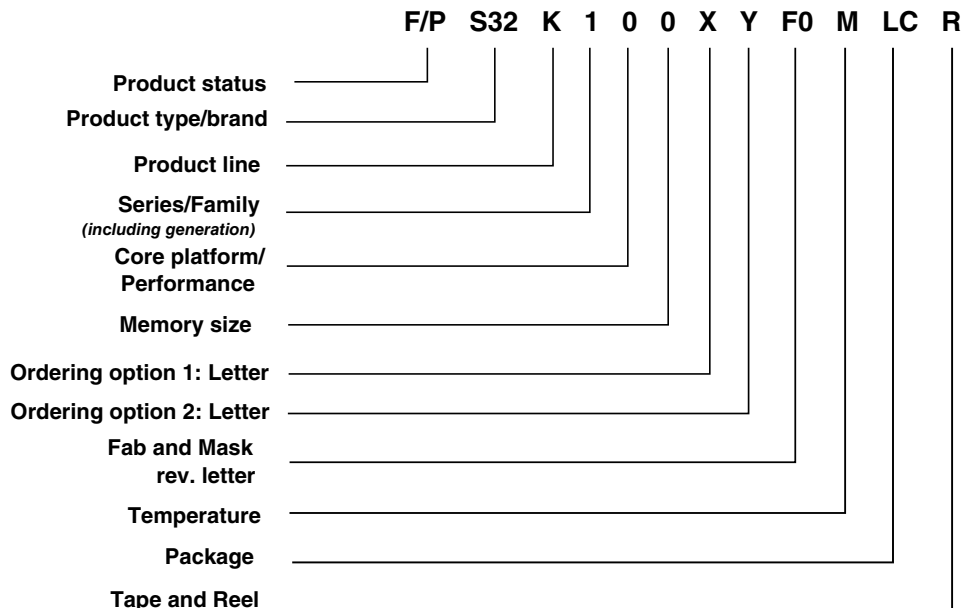
### 3.1 Determining valid orderable parts

To determine the orderable part numbers for this device, go to [www.nxp.com](http://www.nxp.com) and perform a part number search. Additionally see the attachment *S32K\_Part\_Numbers.xlsx* .

#### **NOTE**

Not all part number combinations exist

### 3.2 Ordering information



**Product status**

P: Prototype  
F: Qualified ordering P/N

**Product type/brand**

S32: Automotive 32-bit MCU

**Product line**

K: ARM Cortex MCUs  
M: MagniV/Mixed Signal

**Series/Family**

1: 1st product series  
2: 2nd product series

**Core platform/Performance**

1: ARM Cortex M0+  
4: ARM Cortex M4F

**Memory size**

	2	4	6	8
M0+	32 K	64 K	128 K	256 K
M4F	256 K	512 K	1 M	2 M

**Ordering option**

X: Speed  
B: 48 MHz without DMA (only for S32K11x)  
L: 48 MHz with DMA (only for S32K11x)  
M: 64 MHz  
H: 80 MHz  
U: 112 MHz

**Y: Optional feature**

N: No/None  
R: Max. RAM  
F: CAN-FD and FlexIO including max. RAM  
S: Security including max. RAM  
A: CAN-FD, FlexIO, and Security including max. RAM  
E: Ethernet and audio including max. RAM  
J: CAN FD, FlexIO, Security, Ethernet and audio including max. RAM

**Fab and Mask rev. letter**

Fx: ATMC  
Tx: GF  
XX: Flex #

x0: 1st fab revision  
x1: 2nd fab revision

**Temperature**

C: -40C to 85C  
V: -40C to 105C  
M: -40C to 125C

**Package**

Pins	LQFP	LQFP-EP	QFN	BGA
32	LC	-	FM	-
48	LF	KF	FT	-
64	LH	KH	-	-
100	LL	-	-	MH
144	LQ	-	-	-
176	LU	-	-	-

**Tape and Reel**

T: Trays and Tubes  
R: Tape and Reel

Figure 4. Ordering information

## 4 General

### 4.1 Absolute maximum ratings

#### NOTE

Functional operating conditions appear in the DC electrical characteristics. Absolute maximum ratings are stress ratings only, and functional operation at the maximum values is not guaranteed. See footnotes in the following table for specific conditions.

Stress beyond the listed maximum values may affect device reliability or cause permanent damage to the device.

All the limits defined in the datasheet specification must be honored together and any violation to any one or more will not guarantee desired operation.

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Conditions <sup>1</sup>	Min	Max	Unit
$V_{DD}$ <sup>2</sup>	2.7 V - 5V input supply voltage	—	-0.3	5.8 <sup>3</sup>	V
$V_{REFH}$	3.3 V / 5.0 V ADC high reference voltage	—	-0.3	5.8 <sup>3</sup>	V
$I_{INJPAD\_DC\_ABS}$ <sup>4</sup>	Continuous DC input current (positive / negative) that can be injected into an I/O pin	—	-3	+3	mA
$V_{IN\_DC}$	Continuous DC Voltage on any I/O pin with respect to $V_{SS}$	—	-0.8	5.8 <sup>5</sup>	V
$I_{INJSUM\_DC\_ABS}$	Sum of absolute value of injected currents on all the pins (Continuous DC limit)	—	—	30	mA
$T_{ramp}$ <sup>6</sup>	Supply ramp rate	—	0.5 V/min	500 V/ms	—
$T_A$ <sup>7</sup>	Ambient temperature	—	-40	125	°C
$T_{STG}$	Storage temperature	—	-55	165	°C
$V_{IN\_TRANSIENT}$	Transient overshoot voltage allowed on I/O pin beyond $V_{IN\_DC}$ limit	—	—	6.8 <sup>8</sup>	V

- All voltages are referred to  $V_{SS}$  unless otherwise specified.
- As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
- 60 s lifetime – No restrictions i.e. The part can switch.  
10 hours lifetime – Device in reset i.e. The part cannot switch.
- When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.
- While respecting the maximum current injection limit
- Limit applies to both maximum absolute maximum ramp rate and typical operating conditions.
- $T_J$  (Junction temperature)=135 °C. Assumes  $T_A$ =125 °C for RUN mode

## General

$T_J$  (Junction temperature)=125 °C. Assumes  $T_A$ =105 °C for HSRUN mode

- Assumes maximum  $\theta_{JA}$  for 2s2p board. See [Thermal characteristics](#)

8. 60 seconds lifetime; device in reset (no outputs enabled/toggling)

## 4.2 Voltage and current operating requirements

### NOTE

Full functionality/specifications cannot be guaranteed when voltage drops below 2.7 V.

**Table 2. Voltage and current operating requirements 1**

Symbol	Description	Min.	Max.	Unit	Notes
$V_{DD}^2$	Supply voltage	2.7 <sup>3</sup>	5.5	V	4
$V_{DD\_OFF}$	Voltage allowed to be developed on $V_{DD}$ pin when it is not powered from any external power supply source.	0	0.1	V	
$V_{DDA}$	Analog supply voltage	2.7	5.5	V	4
$V_{DD} - V_{DDA}$	$V_{DD}$ -to- $V_{DDA}$ differential voltage	-0.1	0.1	V	
$V_{REFH}$	ADC reference voltage high	2.7	$V_{DDA} + 0.1$	V	5
$V_{REFL}$	ADC reference voltage low	-0.1	0.1	V	
$V_{ODPU}$	Open drain pullup voltage level	$V_{DD}$	$V_{DD}$	V	6
$I_{INJPAD\_DC\_OP}^7$	Continuous DC input current (positive / negative) that can be injected into an I/O pin	-3	+3	mA	
$I_{INJSUM\_DC\_OP}$	Continuous total DC input current that can be injected across all I/O pins such that there's no degradation in accuracy of analog modules: ADC and ACMP (See section <a href="#">Analog Modules</a> )	—	30	mA	

- Typical conditions assumes  $V_{DD} = V_{DDA} = V_{REFH} = 5$  V, temperature = 25 °C and typical silicon process unless otherwise stated.
- As  $V_{DD}$  varies between the minimum value and the absolute maximum value the analog characteristics of the I/O and the ADC will both change. See section [I/O parameters](#) and [ADC electrical specifications](#) respectively for details.
- S32K148 will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged S32K148 is guaranteed to operate from 2.97 V. All other S32K family devices operate from 2.7 V in all modes.
- $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note [AN5032](#) for reference supply design for SAR ADC.
- $V_{REFH}$  should always be equal to or less than  $V_{DDA} + 0.1$  V and  $V_{DD} + 0.1$  V
- Open drain outputs must be pulled to  $V_{DD}$ .
- When input pad voltage levels are close to  $V_{DD}$  or  $V_{SS}$ , practically no current injection is possible.

### 4.3 Thermal operating characteristics

**Table 3. Thermal operating characteristics for 64 LQFP, 100 LQFP, and 100 MAP-BGA packages.**

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$T_A$ C-Grade Part	Ambient temperature under bias	-40	—	85 <sup>1</sup>	°C
$T_J$ C-Grade Part	Junction temperature under bias	-40	—	105 <sup>1</sup>	°C
$T_A$ V-Grade Part	Ambient temperature under bias	-40	—	105 <sup>1</sup>	°C
$T_J$ V-Grade Part	Junction temperature under bias	-40	—	125 <sup>1</sup>	°C
$T_A$ M-Grade Part	Ambient temperature under bias	-40	—	125 <sup>2</sup>	°C
$T_J$ M-Grade Part	Junction temperature under bias	-40	—	135 <sup>2</sup>	°C

1. Values mentioned are measured at  $\leq 112$  MHz in HSRUN mode.
2. Values mentioned are measured at  $\leq 80$  MHz in RUN mode.

## 4.4 Power and ground pins

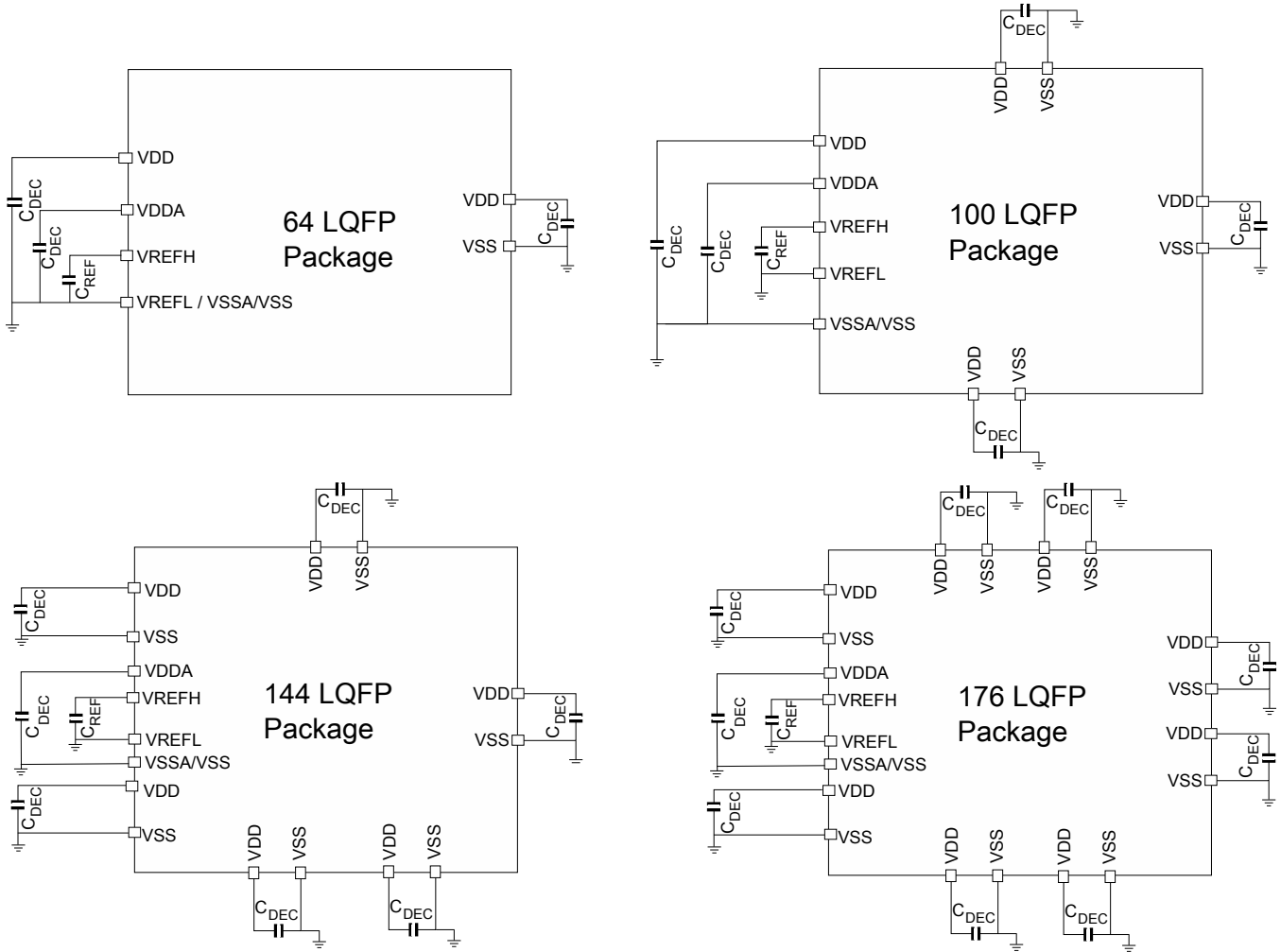


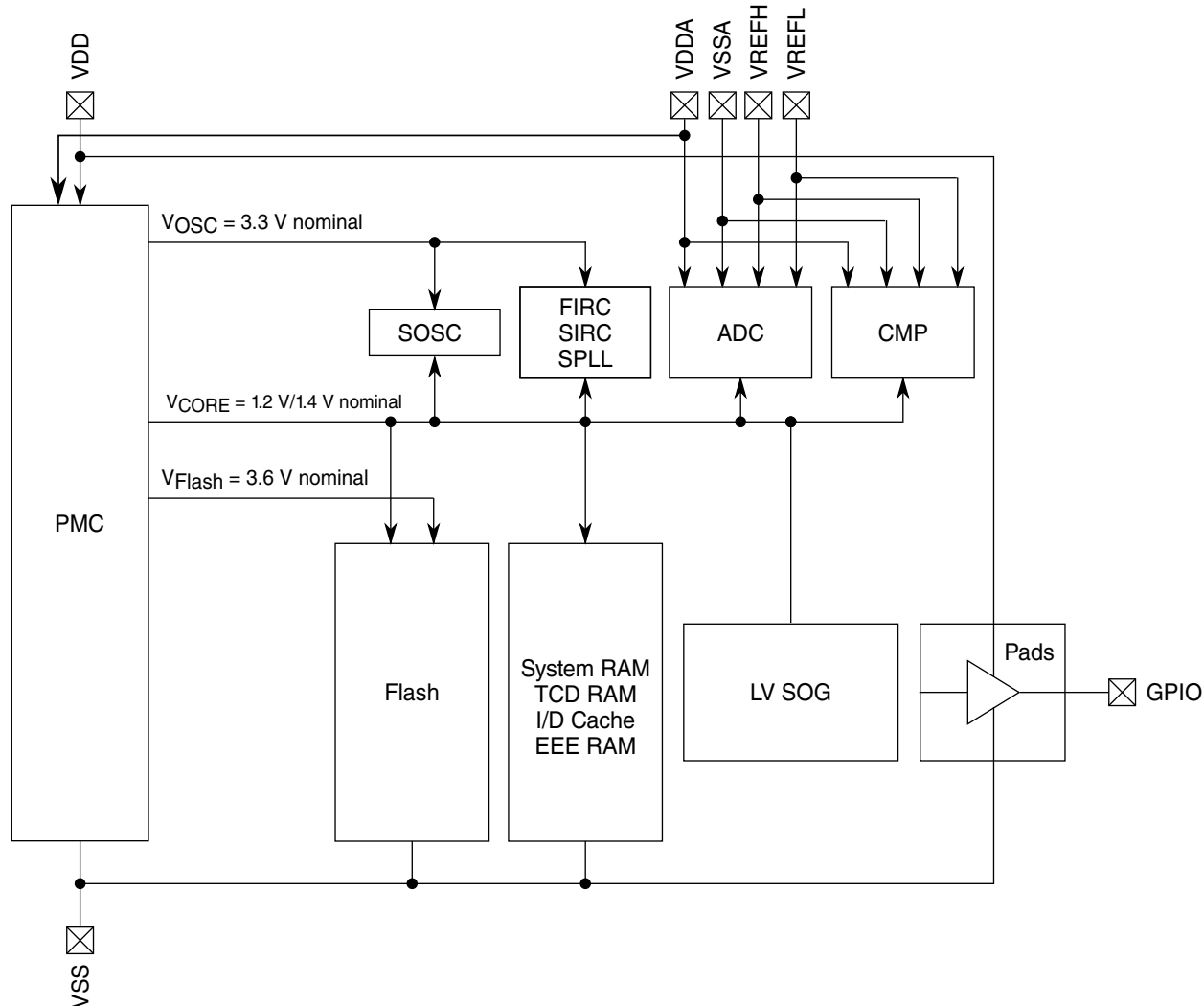
Figure 5. Pinout decoupling

Table 4. Supplies decoupling capacitors 1, 2

Symbol	Description	Min. <sup>3</sup>	Typ.	Max.	Unit
$C_{REF}^{4, 5}$	ADC reference high decoupling capacitance	70	100	—	nF
$C_{DEC}^{5, 6, 7}$	Recommended decoupling capacitance	70	100	—	nF

- $V_{DD}$  and  $V_{DDA}$  must be shorted to a common source on PCB. Appropriate decoupling capacitors to be used to filter noise on the supplies. See application note AN5032 for reference supply design for SAR ADC. All  $V_{SS}$  pins should be connected to common ground at the PCB level.
- All decoupling capacitors must be low ESR ceramic capacitors (for example X7R type).
- Minimum recommendation is after considering component aging and tolerance.
- For improved performance, it is recommended to use 10  $\mu$ F, 0.1  $\mu$ F and 1 nF capacitors in parallel.
- All decoupling capacitors should be placed as close as possible to the corresponding supply and ground pins.
- Contact your local Field Applications Engineer for details on best analog routing practices.
- The filtering used for decoupling the device supplies must comply with the following best practices rules:
  - The protection/decoupling capacitors must be on the path of the trace connected to that component.

- No trace exceeding 1 mm from the protection to the trace or to the ground.
- The protection/decoupling capacitors must be as close as possible to the input pin of the device (maximum 2 mm).
- The ground of the protection is connected as short as possible to the ground plane under the integrated circuit.



\*Note: VSSA and VSS are shorted at package level

Figure 6. Power diagram

## 4.5 LVR, LVD and POR operating requirements

Table 5. V<sub>DD</sub> supply LVR, LVD and POR operating requirements

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>POR</sub>	Rising and falling V <sub>DD</sub> POR detect voltage	1.1	1.6	2.0	V	
V <sub>LVR</sub>	LVR falling threshold (RUN, HSRUN, and STOP modes)	2.50	2.58	2.7	V	
V <sub>LVR_HYST</sub>	LVR hysteresis	—	45	—	mV	1
V <sub>LVR_LP</sub>	LVR falling threshold (VLPS/VLPR modes)	1.97	2.22	2.44	V	

Table continues on the next page...

**Table 5. V<sub>DD</sub> supply LVR, LVD and POR operating requirements (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
V <sub>LVD</sub>	Falling low-voltage detect threshold	2.8	2.875	3	V	
V <sub>LVD_HYST</sub>	LVD hysteresis	—	50	—	mV	1
V <sub>LVW</sub>	Falling low-voltage warning threshold	4.19	4.305	4.5	V	
V <sub>LVW_HYST</sub>	LVW hysteresis	—	75	—	mV	1
V <sub>BG</sub>	Bandgap voltage reference	0.97	1.00	1.03	V	

1. Rising threshold is the sum of falling threshold and hysteresis voltage.

## 4.6 Power mode transition operating behaviors

All specifications in the following table assume this clock configuration:

- RUN Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- HSRUN Mode:
  - Clock source: SPLL
  - SYS\_CLK/CORE\_CLK = 112 MHz
  - BUS\_CLK = 56 MHz
  - FLASH\_CLK = 28 MHz
- VLPR Mode:
  - Clock source: SIRC
  - SYS\_CLK/CORE\_CLK = 4 MHz
  - BUS\_CLK = 4 MHz
  - FLASH\_CLK = 1 MHz
- STOP1/STOP2 Mode:
  - Clock source: FIRC
  - SYS\_CLK/CORE\_CLK = 48 MHz
  - BUS\_CLK = 48 MHz
  - FLASH\_CLK = 24 MHz
- VLPS Mode: All clock sources disabled.

**Table 6. Power mode transition operating behaviors**

Symbol	Description	Min.	Typ.	Max.	Unit
t <sub>POR</sub>	After a POR event, amount of time from the point V <sub>DD</sub> reaches 2.7 V to execution of the first instruction across the operating temperature range of the chip.	—	325	—	μs

Table continues on the next page...

**Table 6. Power mode transition operating behaviors (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit
	VLPS → RUN	8	—	17	μs
	STOP1 → RUN	0.07	0.075	0.08	μs
	STOP2 → RUN	0.07	0.075	0.08	μs
	VLPR → RUN	19	—	26	μs
	VLPR → VLPS	5.75	6.25	6.5	μs
	VLPS → VLPR	26.5	27.25	27.75	μs
	RUN → Compute operation	0.35	0.38	0.4	μs
	HSRUN → Compute operation	0.3	0.31	0.35	μs
	RUN → STOP1	0.35	0.38	0.4	μs
	RUN → STOP2	0.2	0.23	0.25	μs
	RUN → VLPS	0.35	0.38	0.4	μs
	RUN → VLPR	4.4	4.7	5	μs
	VLPS → Asynchronous DMA Wakeup	105	110	125	μs
	STOP1 → Asynchronous DMA Wakeup	1	1.1	1.3	μs
	STOP2 → Asynchronous DMA Wakeup	1	1.1	1.3	μs
	Pin reset → Code execution	—	214	—	μs

**NOTE**

HSRUN should only be used when frequencies in excess of 80 MHz are required. When using 80 MHz and below, RUN mode is the recommended operating mode.

**4.7 Power consumption**

The following table shows the power consumption targets for the device in various mode of operations.

**Table 7. Power consumption (Typicals unless stated otherwise) 1**

Ambient Temperature (°C)		VLPS (µA) <sup>2,3</sup>		VLPR (mA)		STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)		
		Peripherals disabled <sup>6</sup>	Peripherals enabled	Peripherals disabled	Peripherals enabled			Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled	Peripherals enabled	Peripherals disabled
S32K116	25	Typ	26	38	1.9	2.5	7	12	TBD	TBD	TBD	TBD	TBD	NA
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	40
S32K118	25	Typ	26	38	1.9	2.5	7	12	TBD	TBD	TBD	TBD	TBD	NA
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	42
S32K142	25	Typ	29	42	1.9	2.5	10	15	TBD	TBD	TBD	TBD	TBD	NA
	105	Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
		Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	NA
	125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	60
S32K144	25	Typ	29.8	39.1	1.48	1.50	7	7.7	19.7	26.9	25.1	33.3	30.2	39.6

Table continues on the next page...

**Table 7. Power consumption (Typicals unless stated otherwise) 1 (continued)**

Ambient Temperature (°C)	VLPS (µA) <sup>2,3</sup>		VLPR (mA)	STOP1 (mA)	STOP2 (mA)	RUN@48 MHz (mA)		RUN@64 MHz (mA)		RUN@80 MHz (mA)			
	Typ	Max				20.4	27.1	26.1	33.5	30.5	40		
85	Typ	150	1.72	1.85	7.2	8.1	20.4	27.1	26.1	33.5	30.5	40	
	Max	359	2.60	2.65	8.3	9.2	21.9	28.5	27.8	34.4	32.9	41.5	
	105	Typ	256	1.80	2.10	7.8	8.5	20.6	27.4	26.6	33.8	31.2	40.5
Max		850	2.65	2.70	10.3	10.6	22.7	30	28.3	36.5	33.4	43.3	
125	Max	1960	3.18	3.25	12.2	13	25.3	32.7	35	39.8	37.1	46.5	
	S32K146	Typ	40	5	6	15	20	TBD	TBD	TBD	TBD	TBD	TBD
		Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
Max		TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	
125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	70	80	
	S32K148 <sup>7,8</sup>	Typ	40	5	6	15	20	TBD	TBD	TBD	TBD	TBD	TBD
		Typ	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD
Max		TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	
125	Max	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	TBD	100	110	

1. Typical current numbers are indicative for typical silicon process and may vary based on the silicon distribution and user configuration.
2. This is an average based on the use case described in the Comparator section, whereby the analog sampling is taking place periodically enable the DAC as required. The numbers quoted assumes that only a single ANLCMP is active and the others are disabled
3. Current numbers are for reduced configuration and may vary based on user configuration and silicon process variation.
4. HSRUN mode must not be used at 125°C. Max ambient temperature for HSRUN mode is 105°C.
5. Values mentioned are measured at 25 °C at RUN@80 MHz with peripherals disabled.
6. With PMC\_REGSC[CLKBIASDIS] set to 1. See Reference Manual for details.
7. Above S32K148 data is preliminary targets only
8. The S32K148 data points assume that ENET/QuadSPI/SAI etc. are active. If the same configuration is selected as per the S32K144, the very similar IDD.

### 4.7.1 Modes configuration

Attached *S32K1xx\_Power\_Modes\_Configuration.xlsx* details the modes used in gathering the power consumption data stated in the above table [Table 7](#). For full functionality refer to table: Module operation in available low power modes of the *Reference Manual*.

## 4.8 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>HBM</sub>	Electrostatic discharge voltage, human body model	- 4000	4000	V	1
V <sub>CDM</sub>	Electrostatic discharge voltage, charged-device model				2
	All pins except the corner pins	- 500	500	V	
	Corner pins only	- 750	750	V	
I <sub>LAT</sub>	Latch-up current at ambient temperature of 125 °C	- 100	100	mA	3

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.
3. Determined according to JEDEC Standard JESD78, *IC Latch-Up Test*.

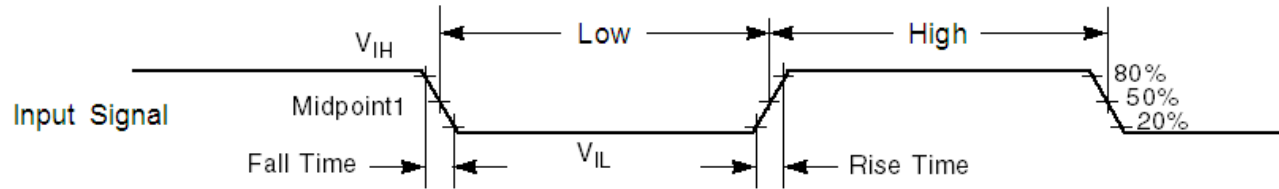
## 4.9 EMC radiated emissions operating behaviors

EMC measurements to IC-level IEC standards are available from NXP on request.

## 5 I/O parameters

### 5.1 AC electrical characteristics

Unless otherwise specified, propagation delays are measured from the 50% to the 50% point, and rise and fall times are measured at the 20% and 80% points, as shown in the following figure.



The midpoint is  $V_{IL} + (V_{IH} - V_{IL})/2$ .

**Figure 7. Input signal measurement reference**

## 5.2 General AC specifications

These general purpose specifications apply to all signals configured for GPIO, UART, and timers.

**Table 8. General switching specifications**

Symbol	Description	Min.	Max.	Unit	Notes
	GPIO pin interrupt pulse width (digital glitch filter disabled) — Synchronous path	1.5	—	Bus clock cycles	1, 2
	GPIO pin interrupt pulse width (digital glitch filter disabled, passive filter disabled) — Asynchronous path	50	—	ns	3
WFRST	RESET input filtered pulse	—	100	ns	4
WFRST	RESET input not filtered pulse	100	—	ns	

1. This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In Stop and VLPS modes, the synchronizer is bypassed so shorter pulses can be recognized in that case.
2. The greater of synchronous and asynchronous timing must be met.
3. These pins do not have a passive filter on the inputs. This is the shortest pulse width that is guaranteed to be recognized.
4. Minimum length of  $\overline{\text{RESET}}$  pulse, guaranteed not to be filtered by the internal filter.

## 5.3 DC electrical specifications at 3.3 V Range

**Table 9. DC electrical specifications at 3.3 V Range**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
$V_{DD}$	I/O Supply Voltage	2.7	3.3	4	V	1
$V_{ih}$	Input Buffer High Voltage	$0.7 \times V_{DD}$	—	$V_{DD} + 0.3$	V	2
$V_{il}$	Input Buffer Low Voltage	$V_{SS} - 0.3$	—	$0.3 \times V_{DD}$	V	3
$V_{hys}$	Input Buffer Hysteresis	$0.06 \times V_{DD}$	—	—	V	
Ioh_Standard	I/O current source capability measured when pad = $(V_{DDE} - 0.8 \text{ V})$	3.5	—	—	mA	

Table continues on the next page...

**Table 9. DC electrical specifications at 3.3 V Range (continued)**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
Iol_Standard	I/O current sink capability measured when pad = 0.8 V	3	—	—	mA	
Ioh_Strong	I/O current source capability measured when pad = (V <sub>DDE</sub> - 0.8 V)	14	—	—	mA	4
Iol_Strong	I/O current sink capability measured when pad = 0.8 V	12	—	—	mA	5
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at V <sub>DD</sub> = 3.3 V					6
	All pins other than high drive port pins		0.005	0.5	μA	
	High drive port pins <sup>7</sup>		0.010	0.5	μA	
R <sub>PU</sub>	Internal pullup resistors	20		60	kΩ	8
R <sub>PD</sub>	Internal pulldown resistors	20		60	kΩ	9

- S32K148 will operate from 2.7 V when executing from internal FIRC. When the PLL is engaged S32K148 is guaranteed to operate from 2.97 V. All other S32K family devices operate from 2.7 V in all modes.
- For reset pads, same V<sub>ih</sub> levels are applicable
- For reset pads, same V<sub>il</sub> levels are applicable
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
- Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *S32K144\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
- When using ENET and SAI on S32K148, the overall device limits associated with high drive pin configurations must be respected i.e. On 144-pin LQFP the general purpose pins: PTA10, PTD0, and PTE4 must be set to low drive.
- Measured at input V = V<sub>SS</sub>
- Measured at input V = V<sub>DD</sub>

## 5.4 DC electrical specifications at 5.0 V Range

**Table 10. DC electrical specifications at 5.0 V Range**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
V <sub>DD</sub>	I/O Supply Voltage	4	—	5.5	V	
V <sub>ih</sub>	Input Buffer High Voltage	0.65 x V <sub>DD</sub>	—	V <sub>DD</sub> + 0.3	V	1
V <sub>il</sub>	Input Buffer Low Voltage	V <sub>SS</sub> - 0.3	—	0.35 x V <sub>DD</sub>	V	2
V <sub>hys</sub>	Input Buffer Hysteresis	0.06 x V <sub>DD</sub>	—	—	V	
Ioh_Standard	I/O current source capability measured when pad = (V <sub>DDE</sub> - 0.8 V)	5	—	—	mA	
Iol_Standard	I/O current sink capability measured when pad = 0.8 V	5	—	—	mA	

Table continues on the next page...

**Table 10. DC electrical specifications at 5.0 V Range (continued)**

Symbol	Parameter	Value			Unit	Notes
		Min.	Typ.	Max.		
Ioh_Strong	I/O current source capability measured when pad = $V_{DDE} - 0.8\text{ V}$	20	—	—	mA	3, 4
Iol_Strong	I/O current sink capability measured when pad = $0.8\text{ V}$	20	—	—	mA	4, 5
IOHT	Output high current total for all ports	—	—	100	mA	
IIN	Input leakage current (per pin) for full temperature range at $V_{DD} = 5.5\text{ V}$					6
	All pins other than high drive port pins		0.005	0.5	$\mu\text{A}$	
	High drive port pins		0.010	0.5	$\mu\text{A}$	
R <sub>PU</sub>	Internal pullup resistors	20		50	k $\Omega$	7
R <sub>PD</sub>	Internal pulldown resistors	20		50	k $\Omega$	8

- For reset pads, same  $V_{ih}$  levels are applicable
- For reset pads, same  $V_{il}$  levels are applicable
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Ioh\_Standard value given above.
- The strong pad I/O pin is capable of switching a 50 pF load at up to 40 MHz.
- The value given is measured at high drive strength mode. For value at low drive strength mode see the Iol\_Standard value given above.
- Several I/O have both high drive and normal drive capability selected by the associated Portx\_PCRn[DSE] control bit. All other GPIOs are normal drive only. For details refer to *SK3K144\_IO\_Signal\_Description\_Input\_Multiplexing.xlsx* attached with the *Reference Manual*.
- Measured at input  $V = V_{SS}$
- Measured at input  $V = V_{DD}$

## 5.5 AC electrical specifications at 3.3 V range

**Table 11. AC electrical specifications at 3.3 V Range**

Symbol	DSE	Rise time (nS) <sup>1</sup>		Fall time (nS) <sup>1</sup>		Capacitance (pF) <sup>2</sup>
		Min.	Max.	Min.	Max.	
Standard	NA	4.6	14.5	3.9	15.7	25
		7.2	23.7	6.2	26.2	50
		24.0	75.4	20.8	88.4	200
Strong	0	4.6	14.5	3.9	15.7	25
		7.2	23.7	6.2	26.2	50
		24.0	75.4	20.8	88.4	200
	1	2.0	5.8	1.8	6.1	25
		2.8	8.0	2.6	8.3	50
		7.0	20.7	6.0	22.4	200

- For reference only. Run simulations with the IBIS model and your custom board for accurate results.
- Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.6 AC electrical specifications at 5 V range

Table 12. AC electrical specifications at 5 V Range

Symbol	DSE	Rise time (nS) <sup>1</sup>		Fall time (nS) <sup>1</sup>		Capacitance (pF) <sup>2</sup>
		Min.	Max .	Min.	Max.	
Standard	NA	3.2	9.4	3.6	10.7	25
		5.4	15.7	5.1	17.4	50
		18.5	52.6	17.6	59.7	200
Strong	0	4.0	9.4	3.6	10.7	25
		5.8	15.7	5.1	17.4	50
		18.1	52.6	17.6	59.7	200
	1	1.6	4.6	1.5	5.0	25
		2.2	5.7	2.2	5.8	50
		5.6	14.6	5.0	15.4	200

1. For reference only. Run simulations with the IBIS model and your custom board for accurate results.
2. Maximum capacitances supported on Standard IOs. However interface or protocol specific specifications might be different, for example for ENET, QSPI etc. . For protocol specific AC specifications, see respective sections.

## 5.7 Standard input pin capacitance

Table 13. Standard input pin capacitance

Symbol	Description	Min.	Max.	Unit
C <sub>IN_D</sub>	Input capacitance: digital pins	—	7	pF

### NOTE

Please refer to [External System Oscillator electrical specifications](#) for EXTAL/XTAL pins.

## 5.8 Device clock specifications

Table 14. Device clock specifications 1

Symbol	Description	Min.	Max.	Unit
High Speed run mode <sup>2</sup>				
f <sub>SYS</sub>	System and core clock	—	112	MHz
f <sub>BUS</sub>	Bus clock	—	56	MHz
f <sub>FLASH</sub>	Flash clock	—	28	MHz
Normal run mode (S32K11x series)				

Table continues on the next page...

**Table 14. Device clock specifications 1 (continued)**

Symbol	Description	Min.	Max.	Unit
$f_{SYS}$	System and core clock	—	48	MHz
$f_{BUS}$	Bus clock	—	24	MHz
$f_{FLASH}$	Flash clock	—	24	MHz
Normal run mode (S32K14x series) <sup>3</sup>				
$f_{SYS}$	System and core clock	—	80	MHz
$f_{BUS}$	Bus clock	—	40	MHz
$f_{FLASH}$	Flash clock	—	26.67	MHz
VLPR mode <sup>4</sup>				
$f_{SYS}$	System and core clock	—	4	MHz
$f_{BUS}$	Bus clock	—	4	MHz
$f_{FLASH}$	Flash clock	—	1	MHz
$f_{ERCLK}$	External reference clock	—	16	MHz

1. Refer to the section [Feature comparison](#) for the availability of modes and other specifications.
2. Only available on some devices. See section [Feature comparison](#).
3. With SPLL as system clock source.
4. The frequency limitations in VLPR mode here override any frequency specification listed in the timing specification for any other module.

## 6 Peripheral operating requirements and behaviors

### 6.1 System modules

There are no electrical specifications necessary for the device's system modules.

### 6.2 Clock interface modules

#### 6.2.1 External System Oscillator electrical specifications

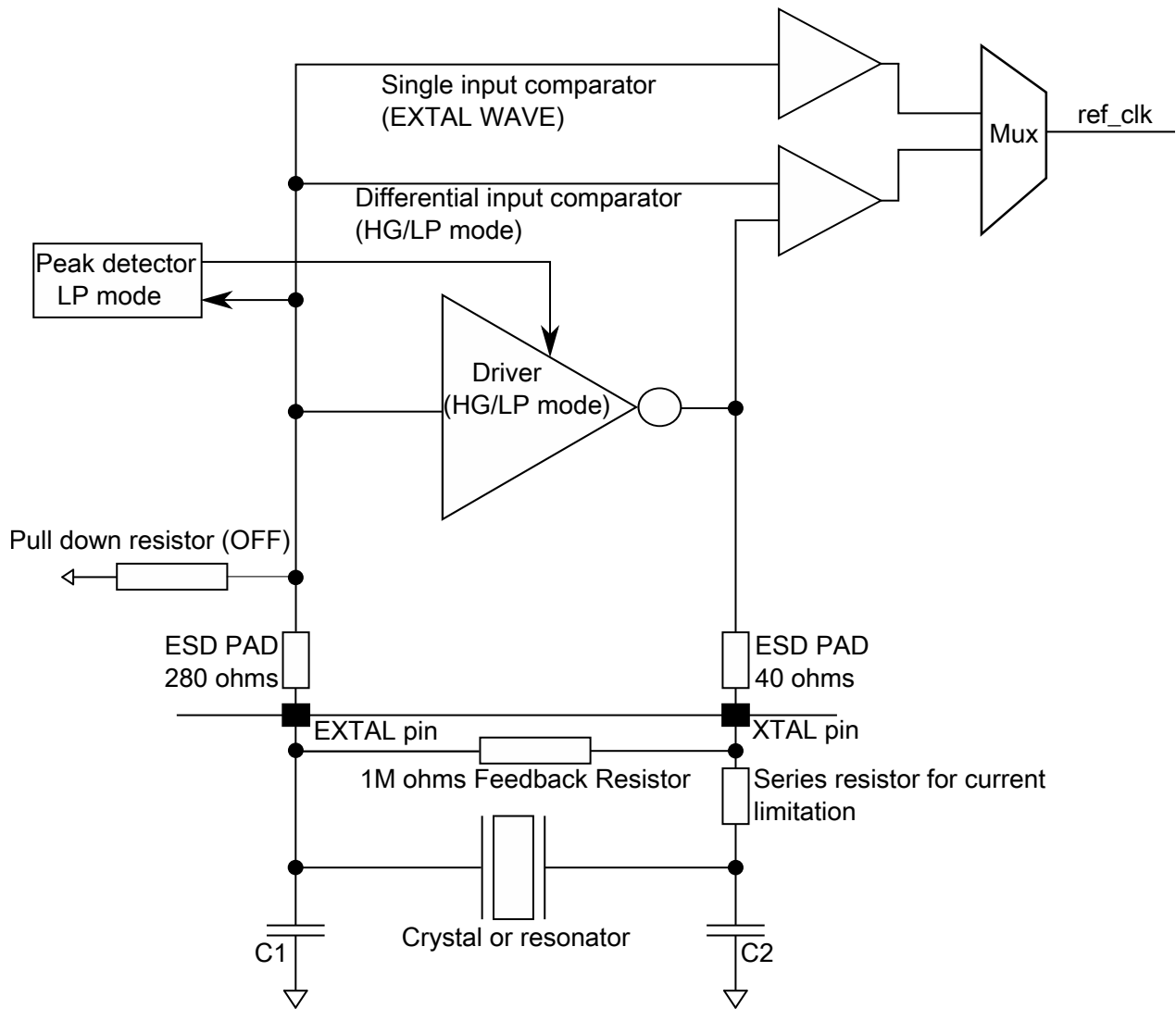


Figure 8. Oscillator connections scheme

Table 15. External System Oscillator electrical specifications

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
g <sub>mXOSC</sub>	Crystal oscillator transconductance					
	4-8 MHz	2.2	—	13.7	mA/V	
	8-40 MHz	16	—	47	mA/V	
V <sub>IL</sub>	Input low voltage — EXTAL pin in external clock mode	V <sub>SS</sub>	—	0.35 * V <sub>DD</sub>	V	
V <sub>IH</sub>	Input high voltage — EXTAL pin in external clock mode	0.7 * V <sub>DD</sub>	—	V <sub>DD</sub>	V	
C <sub>1</sub>	EXTAL load capacitance	—	—	—		1
C <sub>2</sub>	XTAL load capacitance	—	—	—		1
R <sub>F</sub>	Feedback resistor					2
	Low-gain mode (HGO=0)	—	—	—	MΩ	

Table continues on the next page...

**Table 15. External System Oscillator electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
	High-gain mode (HGO=1)	—	1	—	MΩ	
R <sub>S</sub>	Series resistor					
	Low-gain mode (HGO=0)	—	0	—	kΩ	
	High-gain mode (HGO=1)	—	0	—	kΩ	
V <sub>pp</sub>	Peak-to-peak amplitude of oscillation (oscillator mode)					3
	Low-gain mode (HGO=0)	—	1.0	—	V	
	High-gain mode (HGO=1)	—	3.3	—	V	

1. Crystal oscillator circuit provides stable oscillations when  $g_{mXOSC} > 5 * gm\_crit$ . The  $gm\_crit$  is defined as:

$$gm\_crit = 4 * ESR * (2\pi F)^2 * (C_0 + C_L)^2$$

where:

- $g_{mXOSC}$  is the transconductance of the internal oscillator circuit
- ESR is the equivalent series resistance of the external crystal
- F is the external crystal oscillation frequency
- $C_0$  is the shunt capacitance of the external crystal
- $C_L$  is the external crystal total load capacitance.  $C_L = C_s + [C_1 * C_2 / (C_1 + C_2)]$
- $C_s$  is stray or parasitic capacitance on the pin due to any PCB traces
- $C_1, C_2$  external load capacitances on EXTAL and XTAL pins

See manufacture datasheet for external crystal component values

2. • When low-gain is selected, internal R<sub>F</sub> will be selected and external R<sub>F</sub> should not be attached.  
• When high-gain is selected, external R<sub>F</sub> (1 M Ohm) needs to be connected for proper operation of the crystal. For external resistor, up to 5% tolerance is allowed.
3. The EXTAL and XTAL pins should only be connected to required oscillator components and must not be connected to any other devices.

## 6.2.2 External System Oscillator frequency specifications

**Table 16. External System Oscillator frequency specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
f <sub>osc_hi</sub>	Oscillator crystal or resonator frequency	4	—	40	MHz	
f <sub>ec_extal</sub>	Input clock frequency (external clock mode)	—	—	50	MHz	
t <sub>dc_extal</sub>	Input clock duty cycle (external clock mode)	40	50	60	%	
t <sub>cst</sub>	Crystal Start-up Time					
	8 MHz low-gain mode (HGO=0)	—	1.5	—	ms	1
	8 MHz high-gain mode (HGO=1)	—	2.5	—		
	40 MHz low-gain mode (HGO=0)	—	2	—		
40 MHz high-gain mode (HGO=1)	—	2	—			

1. Proper PC board layout procedures must be followed to achieve specifications.

## 6.2.3 System Clock Generation (SCG) specifications

### 6.2.3.1 Fast internal RC Oscillator (FIRC) electrical specifications

Table 17. Fast internal RC Oscillator electrical specifications

Symbol	Parameter <sup>1</sup>	Value			Unit
		Min.	Typ.	Max.	
$F_{\text{FIRC}}$	FIRC target frequency	—	48	—	MHz
$\Delta F$	Frequency deviation across process, voltage, and temperature < 105°C	—	±0.5	±1	% $F_{\text{FIRC}}$
$\Delta F_{125}$	Frequency deviation across process, voltage, and temperature < 125°C	—	±0.5	±1.1	% $F_{\text{FIRC}}$
$T_{\text{Startup}}$	Startup time		3.4	5	$\mu\text{s}^2$
$T_{\text{JIT}}^3$	Cycle-to-Cycle jitter	—	250	500	ps
$T_{\text{JIT}}^3$	Long term jitter over 1000 cycles	—	0.04	0.1	% $F_{\text{FIRC}}$

1. With FIRC regulator enable
2. Startup time is defined as the time between clock enablement and clock availability for system use.
3. FIRC as system clock

#### NOTE

Fast internal RC Oscillator is compliant with CAN and LIN standards.

### 6.2.3.2 Slow internal RC oscillator (SIRC) electrical specifications

Table 18. Slow internal RC oscillator (SIRC) electrical specifications

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$F_{\text{SIRC}}$	SIRC target frequency	—	8	—	MHz
$\Delta F$	Frequency deviation across process, voltage, and temperature < 105°C	—	—	±3	% $F_{\text{SIRC}}$
$\Delta F_{125}$	Frequency deviation across process, voltage, and temperature < 125°C	—	—	±3.3	% $F_{\text{SIRC}}$
$T_{\text{Startup}}$	Startup time	—	9	12.5	$\mu\text{s}^1$

1. Startup time is defined as the time between clock enablement and clock availability for system use.

## 6.2.4 Low Power Oscillator (LPO) electrical specifications

Table 19. Low Power Oscillator (LPO) electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F <sub>LPO</sub>	Internal low power oscillator frequency	113	128	139	kHz
T <sub>startup</sub>	Startup Time	—	—	20	μs

## 6.2.5 SPLL electrical specifications

Table 20. SPLL electrical specifications

Symbol	Parameter	Min.	Typ.	Max.	Unit
F <sub>SPLL_REF</sub> <sup>1</sup>	PLL Reference Frequency Range	8	—	16	MHz
F <sub>SPLL_Input</sub> <sup>2</sup>	PLL Input Frequency	8	—	40	MHz
F <sub>VCO_CLK</sub>	VCO output frequency	180	—	320	MHz
F <sub>SPLL_CLK</sub>	PLL output frequency	90	—	160	MHz
J <sub>CYC_SPLL</sub>	PLL Period Jitter (RMS) <sup>3</sup>				
	at F <sub>VCO_CLK</sub> 180 MHz	—	120	—	ps
	at F <sub>VCO_CLK</sub> 320 MHz	—	75	—	ps
J <sub>ACC_SPLL</sub>	PLL accumulated jitter over 1μs (RMS) <sup>3</sup>				
	at F <sub>VCO_CLK</sub> 180 MHz	—	1350	—	ps
	at F <sub>VCO_CLK</sub> 320 MHz	—	600	—	ps
D <sub>UNL</sub>	Lock exit frequency tolerance	± 4.47	—	± 5.97	%
T <sub>SPLL_LOCK</sub>	Lock detector detection time <sup>4</sup>	—	—	150 × 10 <sup>-6</sup> + 1075(1/F <sub>SPLL_REF</sub> )	s

1. F<sub>SPLL\_REF</sub> is PLL reference frequency range after the PREDIV. For PREDIV and MULT settings refer SCG\_SPLL\_CFG register of Reference Manual.
2. F<sub>SPLL\_Input</sub> is PLL input frequency range before the PREDIV must be limited to the range 8 MHz to 40 MHz. This input source could be derived from a crystal oscillator or some other external square wave clock source using OSC bypass mode. For external clock source settings refer SCG\_SOSCCFG register of Reference Manual.
3. This specification was obtained using a NXP developed PCB. PLL jitter is dependent on the noise characteristics of each PCB and results will vary
4. Lock detector detection time is defined as the time between PLL enablement and clock availability for system use.

## 6.3 Memory and memory interfaces

### 6.3.1 Flash memory module (FTFC) electrical specifications

This section describes the electrical characteristics of the flash memory module.

## 6.3.1.1 Flash timing specifications — commands

Table 21. Flash command timing specifications

Symbol	Description <sup>1</sup>	Min.	Typ.	Max.	Unit	Notes
$t_{rd1blk64k}$	Read 1s Block execution time	—	—	0.5	ms	
$t_{rd1blk512k}$	• 64 KB data flash • 512 KB program flash	—	—	1.8	ms	
$t_{rd1sec2k}$	Read 1s Section execution time (2 KB flash)	—	—	75	$\mu$ s	
$t_{rd1sec4k}$	Read 1s Section execution time (4 KB flash)	—	—	100	$\mu$ s	
$t_{pgmchk}$	Program Check execution time	—	—	95	$\mu$ s	
$t_{pgm8}$	Program Phrase execution time	—	90	150	$\mu$ s	
$t_{ersblk64k}$	Erase Flash Block execution time	—	55	475	ms	2
$t_{ersblk512k}$	• 64 KB data flash • 512 KB program flash	—	435	3700	ms	
$t_{ersscr}$	Erase Flash Sector execution time	—	15	115	ms	2
$t_{pgmsec1k}$	Program Section execution time (1KB flash)	—	5	—	ms	
$t_{rd1allx}$	Read 1s All Blocks execution time	—	—	2.2	ms	
		—	—	4.4	ms	
		—	—	6.6	ms	
$t_{rdonce}$	Read Once execution time	—	—	30	$\mu$ s	
$t_{pgmonce}$	Program Once execution time	—	90	—	$\mu$ s	
$t_{ersall}$	Erase All Blocks execution time	—	500	4200	ms	2
$t_{vfykey}$	Verify Backdoor Access Key execution time	—	—	35	$\mu$ s	
$t_{ersallu}$	Erase All Blocks Unsecure execution time	—	500	4200	ms	2
$t_{pgmpart32k}$	Program Partition for EEPROM execution time	—	70	—	ms	3, 4
$t_{pgmpart64k}$	• 32 KB EEPROM backup • 64 KB EEPROM backup (Non-Interleaved DFlash) • 64 KB EEPROM backup (Interleaved DFlash)	—	71	—	ms	
		—	250	—	ms	
$t_{setramff}$	Set FlexRAM Function execution time:	—	70	—	$\mu$ s	3, 4
$t_{setram32k}$	• Control Code 0xFF • 32 KB EEPROM backup	—	0.8	1.2	ms	
$t_{setram48k}$	• 48 KB EEPROM backup	—	1.0	1.5	ms	
$t_{setram64k}$	• 64 KB EEPROM backup	—	1.3	1.9	ms	
$t_{eewr8b32k}$	Byte-write to FlexRAM execution time:	—	385	1700	$\mu$ s	3, 4
$t_{eewr8b48k}$	• 32 KB EEPROM backup • 48 KB EEPROM backup	—	430	1850	$\mu$ s	
$t_{eewr8b64k}$	• 64 KB EEPROM backup	—	475	2000	$\mu$ s	
$t_{eewr16b32k}$	16-bit write to FlexRAM execution time:	—	385	1700	$\mu$ s	3, 4
$t_{eewr16b48k}$	• 32 KB EEPROM backup	—	430	1850	$\mu$ s	

Table continues on the next page...

**Table 21. Flash command timing specifications (continued)**

Symbol	Description <sup>1</sup>	Min.	Typ.	Max.	Unit	Notes
t <sub>eevr16b64k</sub>	<ul style="list-style-type: none"> <li>48 KB EEPROM backup</li> <li>64 KB EEPROM backup</li> </ul>	—	475	2000	μs	
t <sub>eevr32bers</sub>	32-bit write to erased FlexRAM location execution time	—	360	2000	μs	
t <sub>eevr32b32k</sub>	32-bit write to FlexRAM execution time:	—	630	2000	μs	3, 4
t <sub>eevr32b48k</sub>	<ul style="list-style-type: none"> <li>32 KB EEPROM backup</li> </ul>	—	720	2125	μs	
t <sub>eevr32b64k</sub>	<ul style="list-style-type: none"> <li>48 KB EEPROM backup</li> <li>64 KB EEPROM backup</li> </ul>	—	810	2250	μs	
t <sub>quickwr</sub>	32-bit Quick Write execution time : Time from CCIF clearing (start the write) until CCIF setting (32-bit write complete, ready for next 32-bit write)					
	<ul style="list-style-type: none"> <li>1st 32-bit write</li> </ul>	—	200	550	μs	5, 6
	<ul style="list-style-type: none"> <li>2nd through Next to Last (Nth-1) 32-bit write</li> </ul>	—	150	550	μs	
	<ul style="list-style-type: none"> <li>Last (Nth) 32-bit write (time for write only, not cleanup)</li> </ul>	—	200	550	μs	
t <sub>quickwrCInup</sub>	Quick Write Cleanup execution time	—	—	(Number of Quick Writes) * 2.0	ms	7

- All command times assumes 25 MHz or greater flash clock frequency (for synchronization time between internal/external clocks).
- Maximum times for erase parameters based on expectations at cycling end-of-life.
- For all EEPROM Emulation terms, the specified timing shown assumes previous record clean up has occurred. This may be verified by executing FCCOB Command 0x77, and checking FCCOB number 5 contents show 0x00 - No EEPROM issues detected.
- 'First time' EERAM writes after a Reset or SETRAM may incur additional overhead for EEE cleanup, resulting in up to 2x the times shown.
- For 'Typ.', only after the Nth write completes will any data will be valid. Emulated EEPROM record scheme cleanup overhead may occur after this point even after a brownout or reset. If power or reset occurs before the Nth write completes, the last valid record set will still be valid and the new records will be discarded.
- Quick Write may take up to 550 μs as additional cleanup may occur when crossing sector boundaries.
- Time for emulated EEPROM record scheme overhead cleanup. Automatically done after last (Nth) write completes, assuming still powered. Or via SETRAM cleanup execution command is requested at a later point.

**NOTE**

Under certain circumstances FlexMEM maximum times may be exceeded. In this case the user or application may wait, or assert reset to the FTFC macro to stop the operation.

**6.3.1.2 Reliability specifications****Table 22. NVM reliability specifications**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
When using as Program and Data Flash						

Table continues on the next page...

**Table 22. NVM reliability specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit	Notes
$t_{nvmretp1k}$	Data retention after up to 1 K cycles	20	—	—	years	
$n_{nvmcyep}$	Cycling endurance	1 K	—	—	cycles	2, 1
When using FlexMemory feature: FlexRAM as Emulated EEPROM						
$t_{nvmretee}$	Data retention	5	—	—	years	
$n_{nvmwree16}$	Write endurance	100 K	—	—	writes	3, 4, 5
$n_{nvmwree256}$	<ul style="list-style-type: none"> <li>EEPROM backup to FlexRAM ratio = 16</li> <li>EEPROM backup to FlexRAM ratio = 256</li> </ul>	1.6 M	—	—	writes	

1. Program and Erase for PFlash and DFlash are supported across product temperature specification in Normal Mode (not supported in HSRUN mode).
2. Cycling endurance is per DFlash or PFlash Sector.
3. FlexMemory write endurance specified for 16-bit and/or 32-bit writes to FlexRAM and is supported across standard temperature specification in Normal Mode (not supported in HSRUN mode). Greater write endurance may be achieved with larger ratios of EEPROM backup to FlexRAM.
4. For usage of any other EEE driver other than the FlexMemory feature, the endurance specification will fall back to the specified endurance value of the D-Flash specification (1 K).
5. [EEE calculator tool](#) is available at NXP web site to help estimate the maximum write endurance achievable at specific EEPROM/FlexRAM ratio. The “In Spec” portions of the online calculator refer to the NVM reliability specifications section of data sheet. This calculator is only applies to the FlexMemory feature.

### 6.3.2 QuadSPI AC specifications

The following table describes the QuadSPI electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.
- Add 50 ohm series termination on board in QuadSPI SCK for Flash A to avoid loop back reflection when using in Internal DQS (PAD Loopback) mode.
- For non-Quad mode of operation if external device doesn't have pull-up feature, external pull-up needs to be added at board level for non-used pads.
- With external pull-up, performance of the interface may degrade based on load associated with external pull-up.

**Table 23. QuadSPI electrical specifications**

FLASH PORT	Sym	Unit	FLASH A											
			RUN <sup>1</sup>						HSRUN <sup>1</sup>					
			SDR						SDR					
			Internal Sampling			Internal DQS			Internal Sampling			Internal DQS		
N1		PAD Loopback	Internal Loopback		N1	N1		PAD Loopback		Internal Loopback				
Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max			
Register Settings														
MCR[DDR_EN]		-	0	0	0	0	0	0	0	0	0	0		
MCR[DQS_EN]		-	0	1	1	0	0	0	1	1	1	0		
MCR[SCLKCFG[0]]		-	-	1	0	-	-	-	1	1	0	0		
MCR[SCLKCFG[1]]		-	-	1	0	-	-	-	1	1	0	0		
MCR[SCLKCFG[2]]		-	-	-	-	-	-	-	-	-	-	-		
MCR[SCLKCFG[3]]		-	-	-	-	-	-	-	-	-	-	-		
MCR[SCLKCFG[5]]		-	-	-	-	-	-	-	-	-	-	-		
SMPR[FSPHS]		-	0	1	0	0	0	0	1	1	0	0		
SMPR[FSPLY]		-	0	0	0	0	0	0	0	0	0	0		
SOCCR		-	-	0	23	-	-	-	0	0	30	-		
[SOCCFG[7:0]]		-	-	-	-	-	-	-	-	-	-	-		
SOCCR[SOCCFG[15:8]]		-	-	-	-	-	-	-	-	-	-	-		
FLSHCR[TDH]		-	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00	0x00		
Timing Parameters														
SCK Clock Frequency	f <sub>sck</sub>	MHz	-	38	-	48	-	40	-	80	-	50		
SCK Clock Period	t <sub>sck</sub>	ns	1/f <sub>sck</sub>	-	1/f <sub>sck</sub>	-	1/f <sub>sck</sub>	-	1/f <sub>sck</sub>	-	1/f <sub>sck</sub>	-		

Table continues on the next page...

Table 23. QuadSPI electrical specifications (continued)

FLASH PORT	Sym	Unit	FLASH A															
			RUN <sup>1</sup>						HSRUN <sup>1</sup>									
			Internal Sampling			Internal DQS			Internal Sampling			Internal DQS						
N1			PAD Loopback			Internal Loopback			N1			PAD Loopback			Internal Loopback			
	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
SCK Duty Cycle	t <sub>SDC</sub>	ns	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 1.5	t <sub>SK/2</sub> + 1.5	t <sub>SK/2</sub> - 2.5	t <sub>SK/2</sub> - 2.5
Data Input Setup Time	t <sub>IS</sub>	ns	15	-	2.5	-	10	-	14	-	1.5	-	9	-	1	-	25	0
Data Input Hold Time	t <sub>IH</sub>	ns	0	-	1	-	1	-	0	-	1	-	1	-	1	-	0	0
Data Output Valid Time	t <sub>OV</sub>	ns	-	4.5	-	4.5	-	4.5	-	4.5	-	4.5	-	4	-	4	-	5
Data Output In-Valid Time	t <sub>IV</sub>	ns	5	-	5	-	5	-	5	-	3 <sup>5</sup>	-	5	-	5	-	5	5
CS to SCK Time <sup>6</sup>	t <sub>CSCK</sub>	ns	5	-	5	-	5	-	5	-	5	-	5	-	5	-	10	10
SCK to CS Time <sup>7</sup>	t <sub>CSCKS</sub>	ns	5	-	5	-	5	-	5	-	5	-	5	-	5	-	5	5
Output Load		pf	25	25	25	25	25	25	25	25	25	25	25	25	25	25	25	25

1. See Reference Manual for details on mode settings
2. See Reference Manual for details on mode settings
3. Valid for HyperRAM only
4. RWDS(External DQS CLK) frequency
5. For operating frequency ≤ 64 Mhz, Output invalid time is 5 ns.
6. Program register value QuadSPI\_FLASHCR[TCSS] = 4'h2
7. Program register value QuadSPI\_FLASHCR[TCSH] = 4'h1

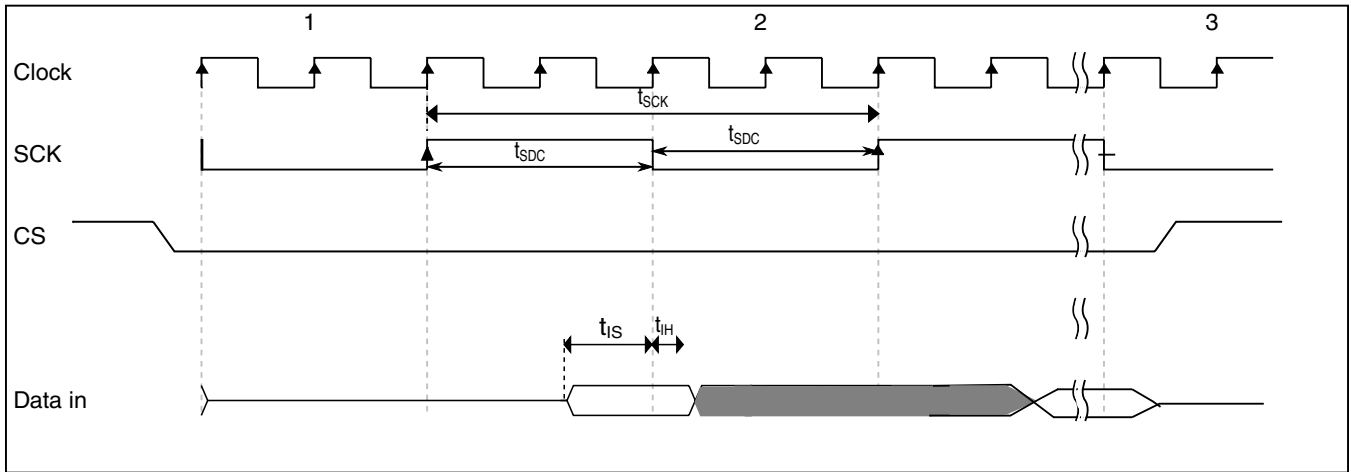


Figure 9. QuadSPI input timing (SDR mode) diagram

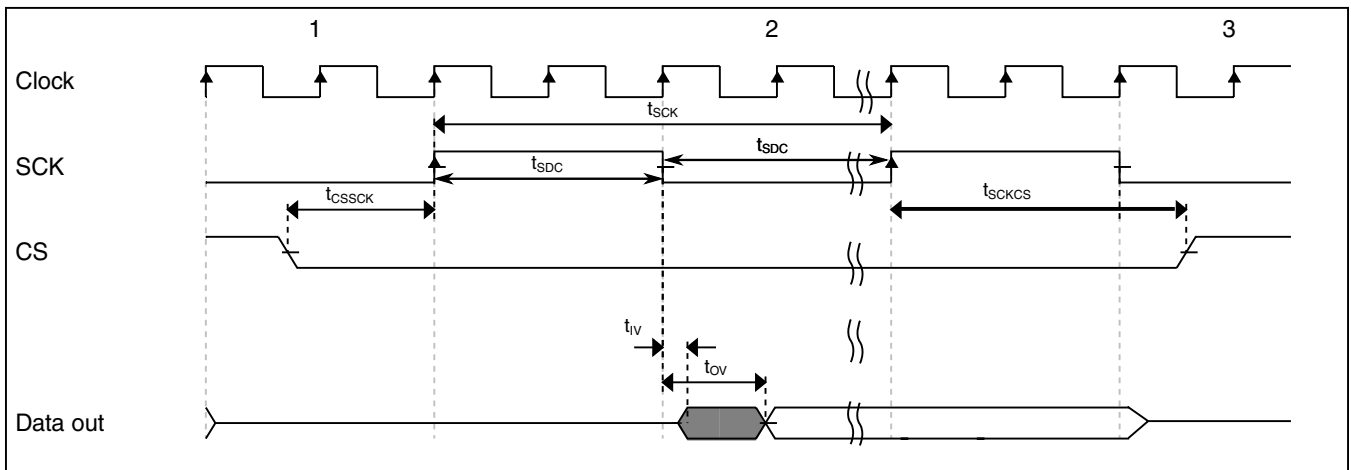


Figure 10. QuadSPI output timing (SDR mode) diagram

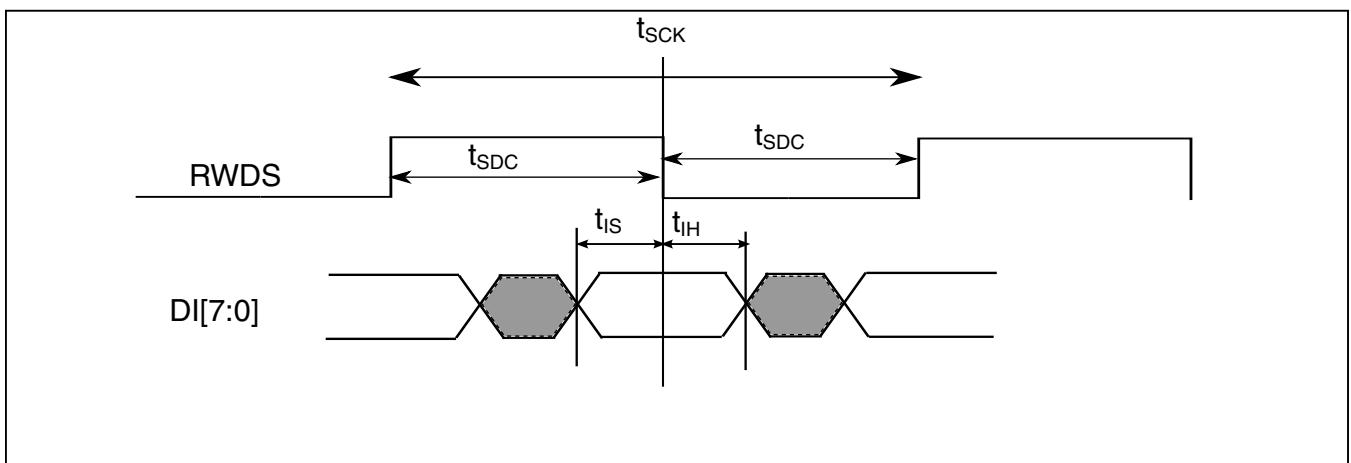


Figure 11. QuadSPI input timing (HyperRAM mode) diagram

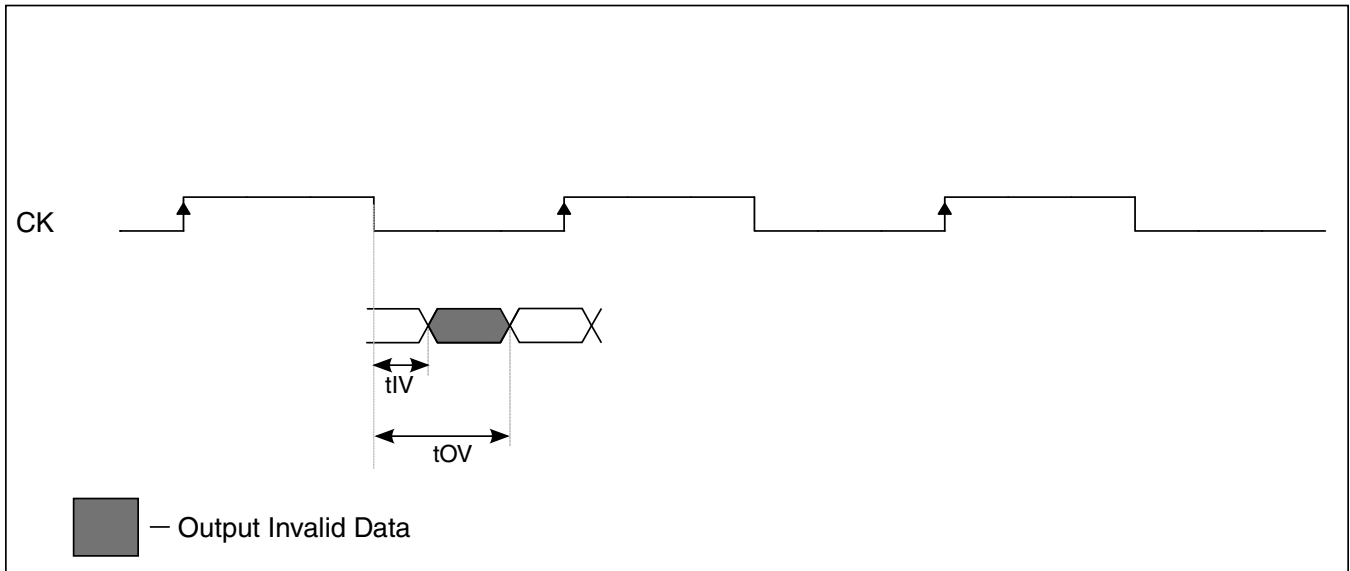


Figure 12. QuadSPI output timing (HyperRAM mode) diagram

## 6.4 Analog modules

### 6.4.1 ADC electrical specifications

#### 6.4.1.1 12-bit ADC operating conditions

Table 24. 12-bit ADC operating conditions

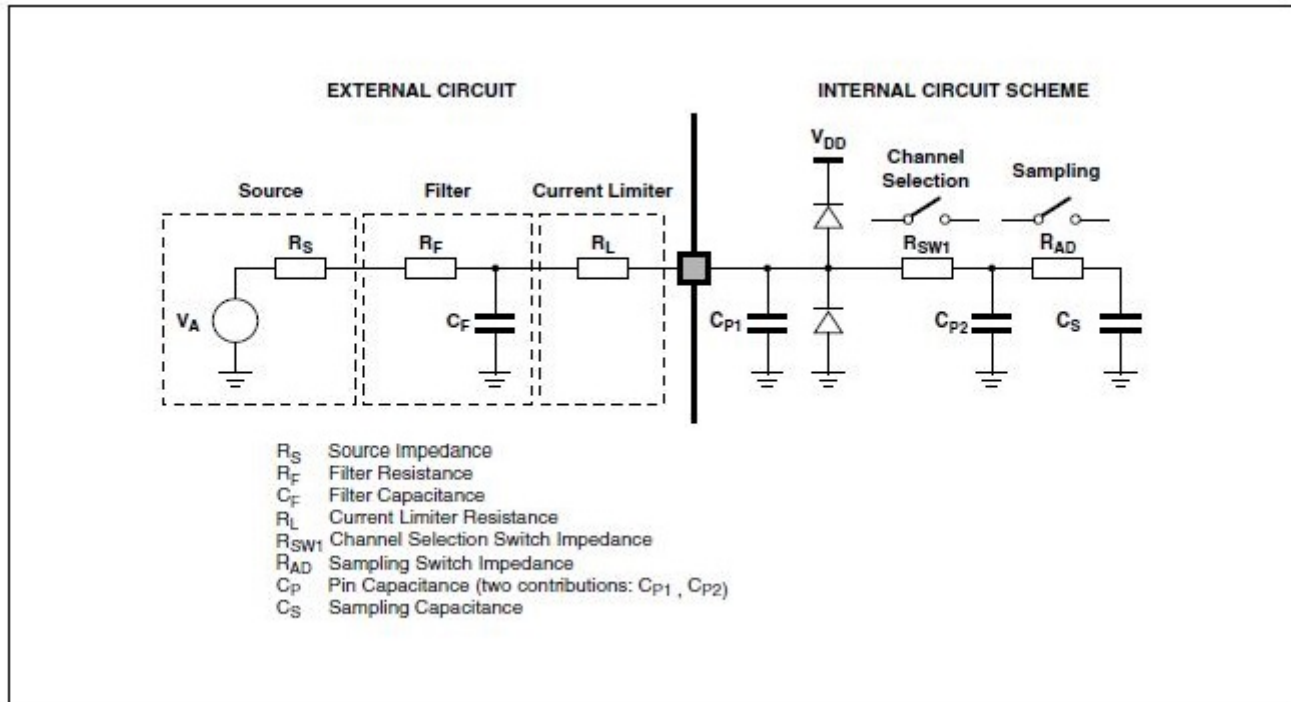
Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
$\Delta V_{DDA}$	Supply voltage	Delta to $V_{DD}$ ( $V_{DD} - V_{DDA}$ )	-0.1	0	+0.1	V	2
$V_{REFH}$	ADC reference voltage high		See Voltage and current operating requirements for values	$V_{DDA}$	See Voltage and current operating requirements for values	V	3
$V_{REFL}$	ADC reference voltage low		See Voltage and current operating requirements for values	0	See Voltage and current operating requirements for values	mV	3
$V_{ADIN}$	Input voltage		$V_{REFL}$	—	$V_{REFH}$	V	
$R_S$	Source impedence	$f_{ADCK} < 4$ MHz	—	—	5	k $\Omega$	
$R_{SW1}$	Channel Selection Switch Impedance		—	-0.75	1.2	k $\Omega$	
$R_{AD}$	Sampling Switch Impedance		—	2	5	k $\Omega$	
$C_{P1}$	Pin Capacitance		—	10	—	pF	

Table continues on the next page...

**Table 24. 12-bit ADC operating conditions (continued)**

Symbol	Description	Conditions	Min.	Typ. <sup>1</sup>	Max.	Unit	Notes
C <sub>P2</sub>	Analog Bus Capacitance		—	—	4	pF	
C <sub>S</sub>	Sampling capacitance		—	4	5	pF	
f <sub>ADCK</sub>	ADC conversion clock frequency	Normal usage	2	40	50	MHz	4, 5
f <sub>CONV</sub>	ADC conversion frequency	No ADC hardware averaging. <sup>6</sup> Continuous conversions enabled, subsequent conversion time	46.4	928	1160	Ksps	7, 8
		ADC hardware averaging set to 32. <sup>6</sup> Continuous conversions enabled, subsequent conversion time	1.45	29	36.25	Ksps	7, 8

1. Typical values assume V<sub>DDA</sub> = 5 V, Temp = 25 °C, f<sub>ADCK</sub> = 40 MHz, R<sub>AS</sub>=20 Ω, and C<sub>AS</sub>=10 nF unless otherwise stated. Typical values are for reference only, and are not tested in production.
2. DC potential difference.
3. For packages without dedicated V<sub>REFH</sub> and V<sub>REFL</sub> pins, V<sub>REFH</sub> is internally tied to V<sub>DDA</sub>, and V<sub>REFL</sub> is internally tied to V<sub>SS</sub>. To get maximum performance, reference supply quality should be better than SAR ADC. See application note AN5032 for details.
4. Clock and compare cycle need to be set according to the guidelines mentioned in the *Reference Manual*.
5. ADC conversion will become less reliable above maximum frequency.
6. When using ADC hardware averaging, see the *Reference Manual* to determine the most appropriate setting for AVGS.
7. Numbers based on the minimum sampling time of 275 ns.
8. For guidelines and examples of conversion rate calculation, see the *Reference Manual* or download the ADC calculator tool.



**Figure 13. ADC input impedance equivalency diagram**

### 6.4.1.2 12-bit ADC electrical characteristics

#### NOTE

ADC performance specifications are documented using a single ADC. For parallel/simultaneous operation of both ADCs, either for sampling the same channel by both ADCs or for sampling different channels by each ADC, some amount of decrease in performance can be expected. Care must be taken to stagger the two ADC conversions, in particular the sample phase, to minimize the impact of simultaneous conversions.

**Table 25. 12-bit ADC characteristics (2.7 V to 3 V) ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ )**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
$V_{DDA}$	Supply voltage		2.7	—	3	V	
$I_{DDA\_ADC}$	Supply current per ADC		—	0.6	1.5	mA	3
SMPLTS	Sample Time		275	—	Refer to the <i>Reference Manual</i>	ns	
TUE <sup>4</sup>	Total unadjusted error		—	±4	±8	LSB <sup>5</sup>	6, 7, 8, 9
DNL	Differential non-linearity		—	±1.0	—	LSB <sup>5</sup>	6, 7, 8, 9
INL	Integral non-linearity		—	±2.0	—	LSB <sup>5</sup>	6, 7, 8, 9

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH}=V_{DDA}=V_{DD}$ , with the calibration frequency set to half the ADC clock frequency.
2. Typical values assume  $V_{DDA} = 3\text{ V}$ ,  $\text{Temp} = 25\text{ }^\circ\text{C}$ ,  $f_{ADCK} = 40\text{ MHz}$ ,  $R_{AS}=20\text{ }\Omega$ , and  $C_{AS}=10\text{ nF}$ , 100 LQFP package unless otherwise stated.
3. The ADC supply current depends on the ADC conversion rate.
4. Represents total static error, which includes offset and full scale error.
5.  $1\text{ LSB} = (V_{REFH} - V_{REFL})/2^N$
6. The specifications are with averaging and in standalone mode only. Performance may degrade depending upon device use case scenario. When using ADC averaging, refer to the *Reference Manual* to determine the most appropriate settings for AVGS.
7. For ADC signals adjacent to  $V_{DD}/V_{SS}$  or XTAL/EXTAL or high frequency switching pins, some degradation in the ADC performance may be observed.
8. All values guarantee the performance of the ADC for multiple ADC input channel pins. When using ADC to monitor the internal analog parameters, assume minor degradation.
9. All the parameters in the table are given assuming system clock as the clocking source for ADC.

**Table 26. 12-bit ADC characteristics (3 V to 5.5 V)( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ )**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
$V_{DDA}$	Supply voltage		3	—	5.5	V	
$I_{DDA\_ADC}$	Supply current per ADC		—	1	2.1	mA	3
SMPLTS	Sample Time		275	—	Refer to the <i>Reference Manual</i>	ns	

Table continues on the next page...

**Table 26. 12-bit ADC characteristics (3 V to 5.5 V)( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SS}$ ) (continued)**

Symbol	Description	Conditions <sup>1</sup>	Min.	Typ. <sup>2</sup>	Max.	Unit	Notes
TUE <sup>4</sup>	Total unadjusted error		—	±4	±8	LSB <sup>5</sup>	6, 7, 8, 9
DNL	Differential non-linearity		—	±0.7	—	LSB <sup>5</sup>	6, 7, 8, 9
INL	Integral non-linearity		—	±1.0	—	LSB <sup>5</sup>	6, 7, 8, 9

1. All accuracy numbers assume the ADC is calibrated with  $V_{REFH}=V_{DDA}=V_{DD}$ , with the calibration frequency set to half the ADC clock frequency.
2. Typical values assume  $V_{DDA} = 5.0$  V, Temp = 25 °C,  $f_{ADCK} = 40$  MHz,  $R_{AS}=20$  Ω, and  $C_{AS}=10$  nF unless otherwise stated.
3. The ADC supply current depends on the ADC conversion rate.
4. Represents total static error, which includes offset and full scale error.
5. 1 LSB =  $(V_{REFH} - V_{REFL})/2^N$
6. The specifications are with averaging and in standalone mode only. Performance may degrade depending upon device use case scenario. When using ADC averaging, refer to the *Reference Manual* to determine the most appropriate settings for AVGS.
7. For ADC signals adjacent to  $V_{DD}/V_{SS}$  or XTAL/EXTAL or high frequency switching pins, some degradation in the ADC performance may be observed.
8. All values guarantee the performance of the ADC for multiple ADC input channel pins. When using ADC to monitor the internal analog parameters, assume minor degradation.
9. All the parameters in the table are given assuming system clock as the clocking source for ADC.

**NOTE**

When using high speed interfaces such as the QuadSPI, SAI0, SAI1 or ENET there may be some ADC degradation on the adjacent analog input paths. See following table for details.

Pin name	TGATE purpose
PTE8	CMP0_IN3
PTC3	ADC0_SE11/CMP0_IN4
PTC2	ADC0_SE10/CMP0_IN5
PTD7	CMP0_IN6
PTD6	CMP0_IN7
PTD28	ADC1_SE22
PTD27	ADC1_SE21

**6.4.2 CMP with 8-bit DAC electrical specifications**

**Table 28. Comparator with 8-bit DAC electrical specifications**

Symbol	Description	Min.	Typ.	Max.	Unit
I <sub>DDHS</sub>	Supply current, High-speed mode <sup>1</sup>				µA
	-40 - 125 °C	—	230	300	
I <sub>DDL</sub>	Supply current, Low-speed mode <sup>1</sup>				µA
	-40 - 105 °C	—	5	10	
	-40 - 125 °C		5	13	

Table continues on the next page...

**Table 28. Comparator with 8-bit DAC electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit
V <sub>AIN</sub>	Analog input voltage	0	0 - V <sub>DDA</sub>	V <sub>DDA</sub>	V
V <sub>AIO</sub>	Analog input offset voltage, High-speed mode				mV
	-40 - 125 °C	-25	±1	25	
V <sub>AIO</sub>	Analog input offset voltage, Low-speed mode				mV
	-40 - 125 °C	-40	±4	40	
t <sub>DHSB</sub>	Propagation delay, High-speed mode <sup>2</sup>				ns
	-40 - 105 °C	—	30	200	
	-40 - 125 °C		30	300	
t <sub>DLSB</sub>	Propagation delay, Low-speed mode <sup>2</sup>				µs
	-40 - 105 °C	—	0.5	2	
	-40 - 125 °C	—	0.5	3	
t <sub>DHSS</sub>	Propagation delay, High-speed mode <sup>3</sup>				ns
	-40 - 105 °C	—	70	400	
	-40 - 125 °C	—	70	500	
t <sub>DLSS</sub>	Propagation delay, Low-speed mode <sup>3</sup>				µs
	-40 - 105 °C	—	1	5	
	-40 - 125 °C	—	1	5	
t <sub>IDHS</sub>	Initialization delay, High-speed mode <sup>4</sup>				µs
	-40 - 125 °C	—	1.5	3	
t <sub>IDLS</sub>	Initialization delay, Low-speed mode <sup>4</sup>				µs
	-40 - 125 °C	—	10	30	
V <sub>HYST0</sub>	Analog comparator hysteresis, Hyst0 (V <sub>AIO</sub> )				mV
	-40 - 125 °C	—	0	—	
V <sub>HYST1</sub>	Analog comparator hysteresis, Hyst1, High-speed mode				mV
	-40 - 125 °C	—	16	66	
	Analog comparator hysteresis, Hyst1, Low-speed mode				
	-40 - 125 °C	—	11	40	
V <sub>HYST2</sub>	Analog comparator hysteresis, Hyst2, High-speed mode				mV
	-40 - 125 °C	—	32	133	
	Analog comparator hysteresis, Hyst2, Low-speed mode				
	-40 - 125 °C	—	22	80	
V <sub>HYST3</sub>	Analog comparator hysteresis, Hyst3, High-speed mode				mV
	-40 - 125 °C	—	48	200	
	Analog comparator hysteresis, Hyst3, Low-speed mode				
	-40 - 125 °C	—	33	120	

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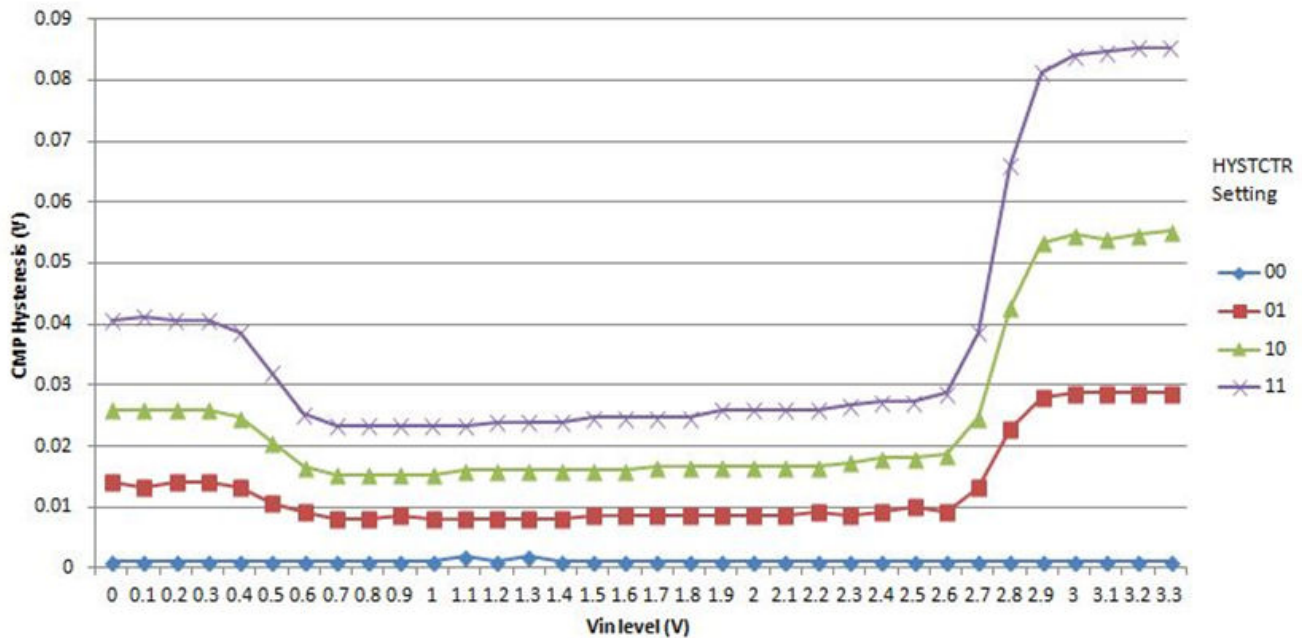
**Table 28. Comparator with 8-bit DAC electrical specifications (continued)**

Symbol	Description	Min.	Typ.	Max.	Unit
I <sub>DAC8b</sub>	8-bit DAC current adder (enabled)				
	3.3V Reference Voltage	—	6	9	μA
	5V Reference Voltage	—	10	16	μA
INL <sup>5</sup>	8-bit DAC integral non-linearity	-0.75	—	0.75	LSB <sup>6</sup>
DNL	8-bit DAC differential non-linearity	-0.5	—	0.5	LSB <sup>6</sup>
t <sub>DDAC</sub>	Initialization and switching settling time	—	—	30	μs

1. Difference at input > 200mV
2. Applied ± (100 mV + V<sub>HYST0/1/2/3</sub>+ max. of V<sub>AIO</sub>) around switch point.
3. Applied ± (30 mV + 2 × V<sub>HYST0/1/2/3</sub>+ max. of V<sub>AIO</sub>) around switch point.
4. Applied ± (100 mV + V<sub>HYST0/1/2/3</sub>).
5. Calculation method used: Linear Regression Least Square Method
6. 1 LSB = V<sub>reference</sub>/256

**NOTE**

For comparator IN signals adjacent to V<sub>DD</sub>/V<sub>SS</sub> or XTAL/EXTAL or switching pins cross coupling may happen and hence hysteresis settings can be used to obtain the desired comparator performance. Additionally, an external capacitor (1nF) should be used to filter noise on input signal. Also, source drive should not be weak (Signal with < 50 K pull up/down is recommended).



**Figure 14. Typical hysteresis vs. Vin level (VDDA = 3.3 V, PMODE = 0)**

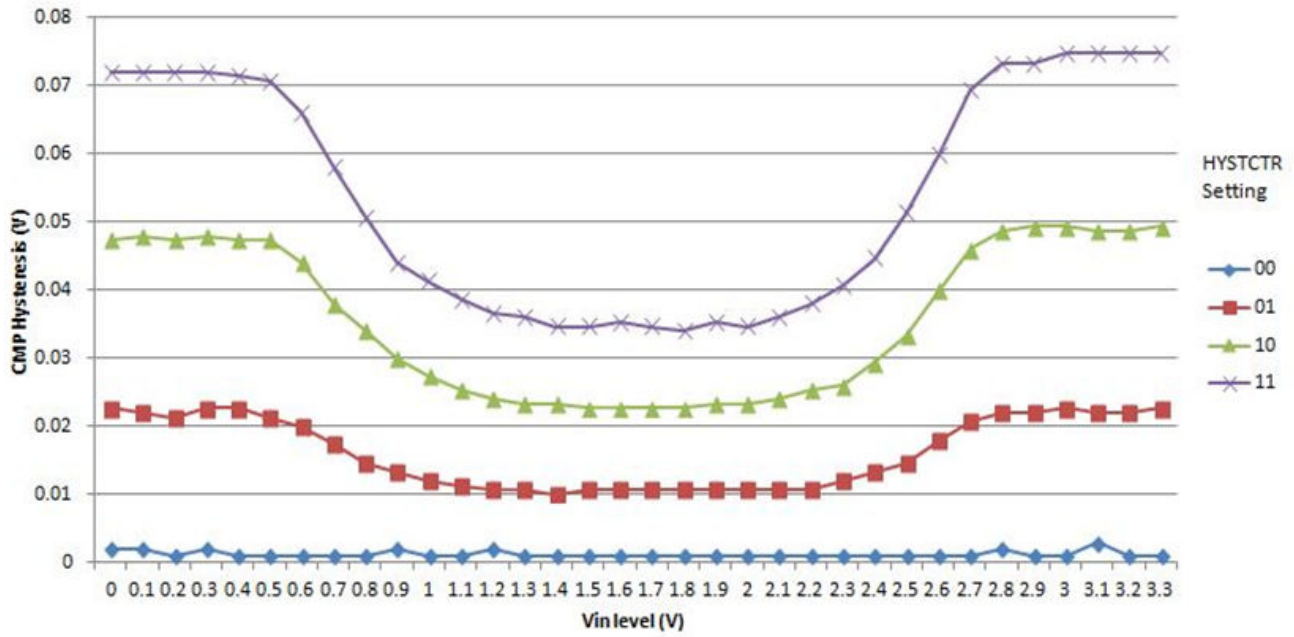


Figure 15. Typical hysteresis vs. Vin level (VDDA = 3.3 V, PMODE = 1)

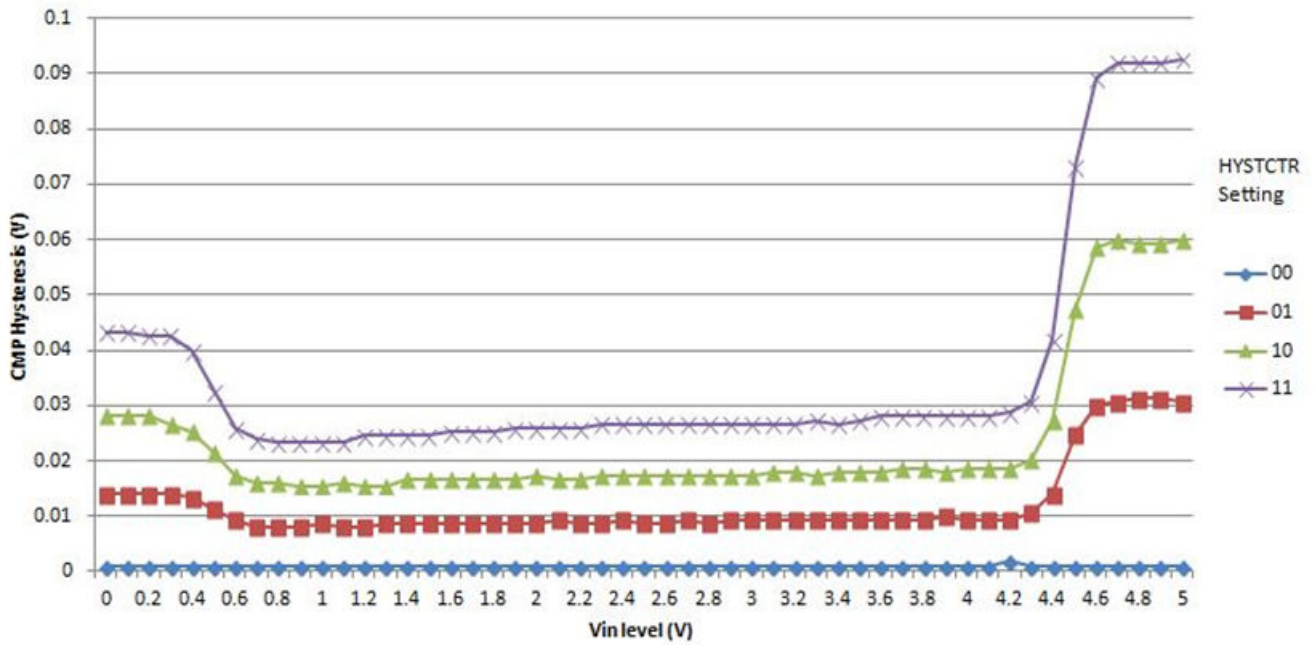


Figure 16. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 0)

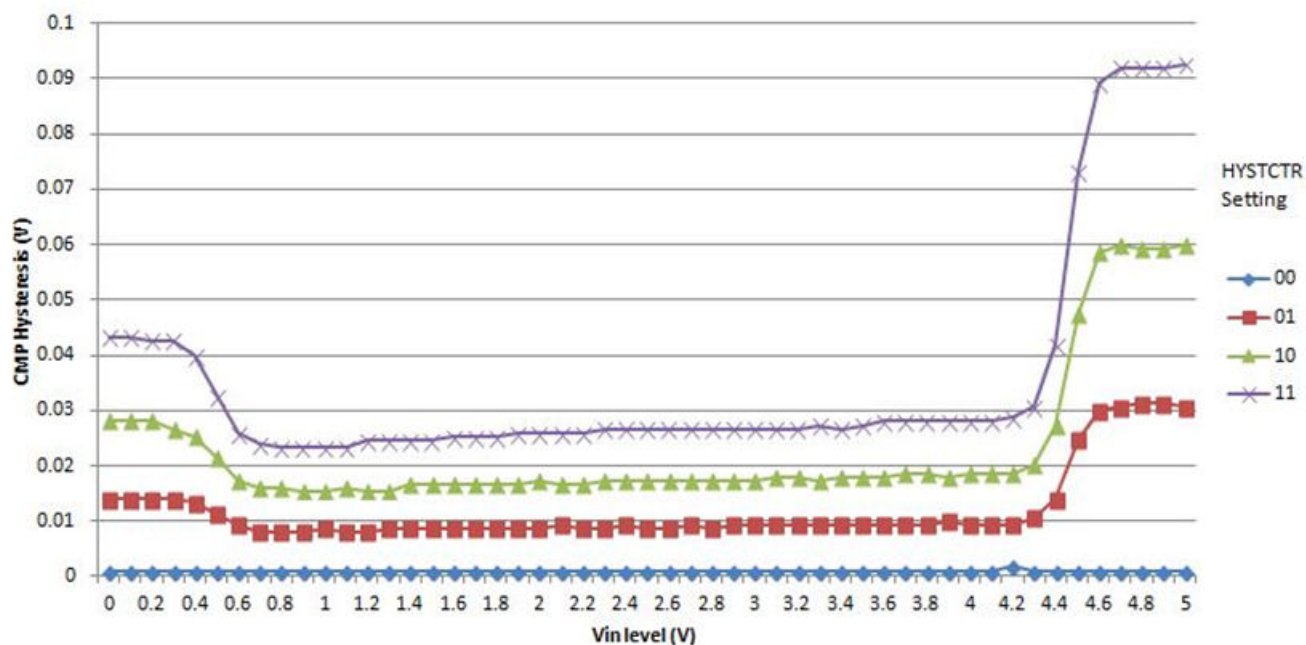


Figure 17. Typical hysteresis vs. Vin level (VDDA = 5 V, PMODE = 1)

## 6.5 Communication modules

### 6.5.1 LPUART electrical specifications

Refer to [General AC specifications](#) for LPUART specifications.

#### 6.5.1.1 Supported baud rate

Baud rate = Baud clock / ((OSR+1) \* SBR).

For details, see section: 'Baud rate generation' of the *Reference Manual*.

### 6.5.2 LPSPI electrical specifications

The Low Power Serial Peripheral Interface (LPSPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic LPSPI timing modes.

- All timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  thresholds.
- All measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew setting ( DSE = 1 ).

**Table 29. LPSPi electrical specifications<sup>1</sup>**

Num	Symbol	Description	Conditions	Run Mode <sup>2</sup>						HSRUN Mode <sup>2</sup>						VL		
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO				
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.			
	$f_{\text{periph}}^{3,4}$	Peripheral Frequency	Slave	-	40	-	40	-	40	-	56	-	56	-	8	5.0 V IO	Min.	Max.
			Master	-	40	-	40	-	40	-	56	-	56	-	8			
			Master Loopback <sup>5</sup>	-	40	-	48	-	48	-	48	-	48	-	8			
			Master Loopback(Slow) <sup>6</sup>	-	48	-	48	-	48	-	48	-	48	-	8			
1	$f_{\text{op}}$	Frequency of operation	Slave	-	10	-	10	-	10	-	14	-	14	-	4			
			Master	-	10	-	10	-	10	-	14	-	14	-	4			
			Master Loopback <sup>5</sup>	-	20	-	12	-	12	-	24	-	12	-	4			
			Master Loopback(slow) <sup>6</sup>	-	12	-	12	-	12	-	12	-	12	-	4			
2	$t_{\text{SPSCK}}$	SPSCK period	Slave	100	-	100	-	72	-	72	-	72	-	250	-			
			Master	100	-	100	-	72	-	72	-	72	-	250	-			
			Master Loopback <sup>5</sup>	50	-	83	-	42	-	42	-	83	-	250	-			
			Master Loopback(slow) <sup>6</sup>	83	-	83	-	83	-	83	-	83	-	250	-			
3	$t_{\text{Lead}}^7$	Enable lead time (PCS to SPSCK delay)	Slave	-	-	-	-	-	-	-	-	-	-	-	-			

Table continues on the next page...

**Table 29. LPSPi electrical specifications 1 (continued)**

Num	Symbol	Description	Conditions	Run Mode <sup>2</sup>				HSRUN Mode <sup>2</sup>				VL			
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		Max.	Min.
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.				
4	t <sub>Lag</sub> <sup>8</sup>	Enable lag time (After SPSCK delay)	Master	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 50	.	
			Master Loopback <sup>5</sup>	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 50	.	
			Master Loopback(slow) <sup>6</sup>	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 50	.	
			Slave	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 25	.	.	(PSSCK + 1) * t <sub>SPSCK</sub> - 50	.	

Table continues on the next page...

**Table 29. LPSPi electrical specifications 1 (continued)**

Num	Symbol	Description	Conditions	Run Mode <sup>2</sup>						HSRUN Mode <sup>2</sup>						VL				
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO						
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.					
5	t <sub>wSPSCK</sub>	Clock(SPSC K) high or low time (SPSCK duty cycle)	Slave	t <sub>SPSCK</sub> /2 - 3	-	5	-	t <sub>SPSCK</sub> /2 - 3	-	3	-	t <sub>SPSCK</sub> /2 + 3	-	5	-	t <sub>SPSCK</sub> /2 - 5	-	18	-	t <sub>SPSCK</sub> /2 + 5
			Master	t <sub>SPSCK</sub> /2 - 3	-	38	-	26	-	37	-	72	-	37	-	72	-	72	-	72
6	t <sub>SU</sub>	Data setup time(inputs)	Master	t <sub>SPSCK</sub> /2 - 3	-	8	-	5	-	5	-	5	-	5	-	5	-	20	-	20
			Master Loopback <sup>5</sup>	t <sub>SPSCK</sub> /2 - 3	-	10	-	7	-	9	-	20	-	9	-	20	-	20	-	20
7	t <sub>HI</sub>	Data hold time(inputs)	Slave	t <sub>SPSCK</sub> /2 - 3	-	3	-	3	-	3	-	3	-	3	-	3	-	14	-	14
			Master	t <sub>SPSCK</sub> /2 - 3	-	0	-	0	-	0	-	0	-	0	-	0	-	0	-	0
8	t <sub>a</sub>	Slave access time	Master	t <sub>SPSCK</sub> /2 - 3	-	3	-	3	-	2	-	3	-	3	-	3	-	11	-	11
			Master Loopback <sup>5</sup>	t <sub>SPSCK</sub> /2 - 3	-	3	-	3	-	3	-	3	-	3	-	3	-	12	-	12
9	t <sub>dis</sub>	Slave MISO (SOUT) disable time	Slave	t <sub>SPSCK</sub> /2 - 3	-	50	-	50	-	50	-	50	-	50	-	50	-	50	-	50
			Slave	t <sub>SPSCK</sub> /2 - 3	-	50	-	50	-	50	-	50	-	50	-	50	-	50	-	50

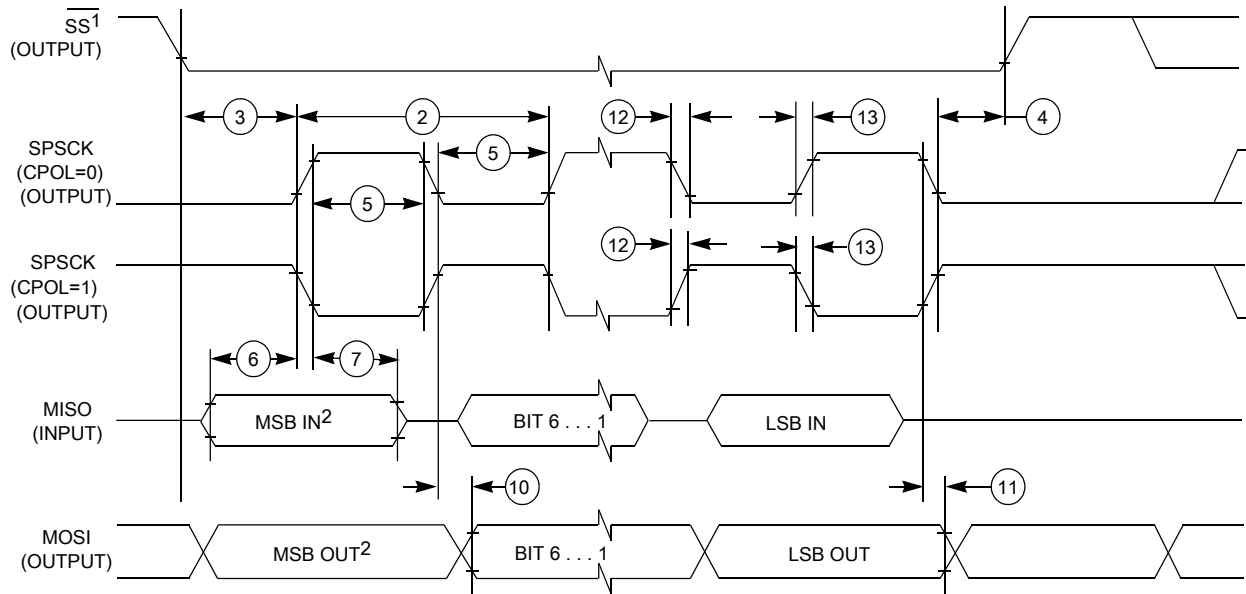
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**Table 29. LPSPi electrical specifications 1 (continued)**

Num	Symbol	Description	Conditions	Run Mode <sup>2</sup>						HSRUN Mode <sup>2</sup>						VI
				5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		
				Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	
10	t <sub>v</sub>	Data valid (after SPSPCK edge)	Slave	-	30	-	39	-	26	-	36	-	92	5.0 V IO	Ma	
			Master	-	12	-	16	-	11	-	15	-	47			
			Master Loopback <sup>5</sup>	-	12	-	16	-	11	-	15	-	47			
			Master Loopback(slow) <sup>6</sup>	-	8	-	10	-	7	-	9	-	44			
11	t <sub>HO</sub>	Data hold time(outputs)	Slave	4	-	4	-	4	-	4	-	4	-	4	-	
			Master	-15	-	-22	-	-15	-	-22	-	-22	-	-22	-	
			Master Loopback <sup>5</sup>	-10	-	-14	-	-10	-	-14	-	-14	-	-14	-	
			Master Loopback(slow) <sup>6</sup>	-15	-	-22	-	-15	-	-22	-	-22	-	-21	-	
12	t <sub>RI/FI</sub>	Rise/Fall time input	Slave	-	1	-	1	-	1	-	1	-	1	-	1	
			Master	-	-	-	-	-	-	-	-	-	-	-	-	
			Master Loopback <sup>5</sup>	-	-	-	-	-	-	-	-	-	-	-	-	
			Master Loopback(slow) <sup>6</sup>	-	-	-	-	-	-	-	-	-	-	-	-	
13	t <sub>RO/FO</sub>	Rise/Fall time output	Slave	-	25	-	25	-	25	-	25	-	25	-	25	
			Master	-	-	-	-	-	-	-	-	-	-	-	-	
			Master Loopback <sup>5</sup>	-	-	-	-	-	-	-	-	-	-	-	-	
			Master Loopback(slow) <sup>6</sup>	-	-	-	-	-	-	-	-	-	-	-	-	

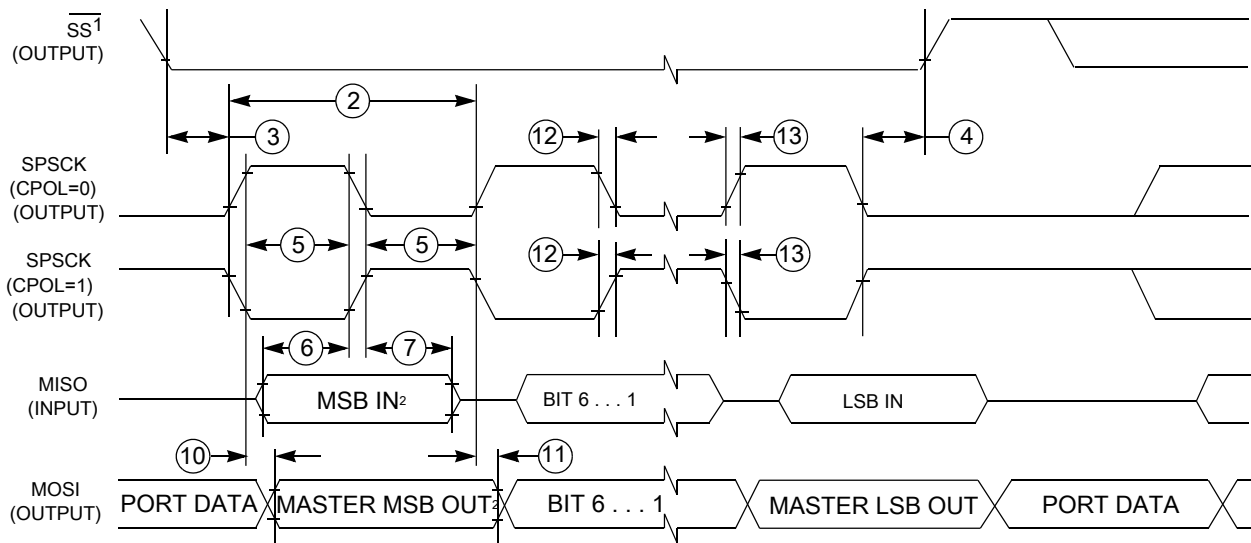
- Trace length should not exceed 11 inches for SCK pad when used in Master loopback mode.
- While transitioning from HSRUN mode to RUN mode, LPSPi output clock should not be more than 14 MHz.
- f<sub>periph</sub> = LPSPi peripheral clock

4.  $t_{\text{periph}} = 1/f_{\text{periph}}$
5. Master Loopback mode - In this mode LPSPI\_SCK clock is delayed for sampling the input data which is enabled by setting LPSPI\_CFG0.Clock pads used are PTD15 and PTE0. Applicable only for LPSPI0.
6. Master Loopback (slow) - In this mode LPSPI\_SCK clock is delayed for sampling the input data which is enabled by setting LPSPI\_CFG0.Clock pad used is PTB2. Applicable only for LPSPI0.
7. Set the PCSSCK configuration bit as 0, for a minimum of 1 delay cycle of LPSPI baud rate clock, where PCSSCK ranges from 0 to 255.
8. Set the SCKPCS configuration bit as 0, for a minimum of 1 delay cycle of LPSPI baud rate clock, where SCKPCS ranges from 0 to 255.



1. If configured as an output.
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 18. LPSPI master mode timing (CPHA = 0)**



1. If configured as output
2. LSBF = 0. For LSBF = 1, bit order is LSB, bit 1, ..., bit 6, MSB.

**Figure 19. LPSPI master mode timing (CPHA = 1)**

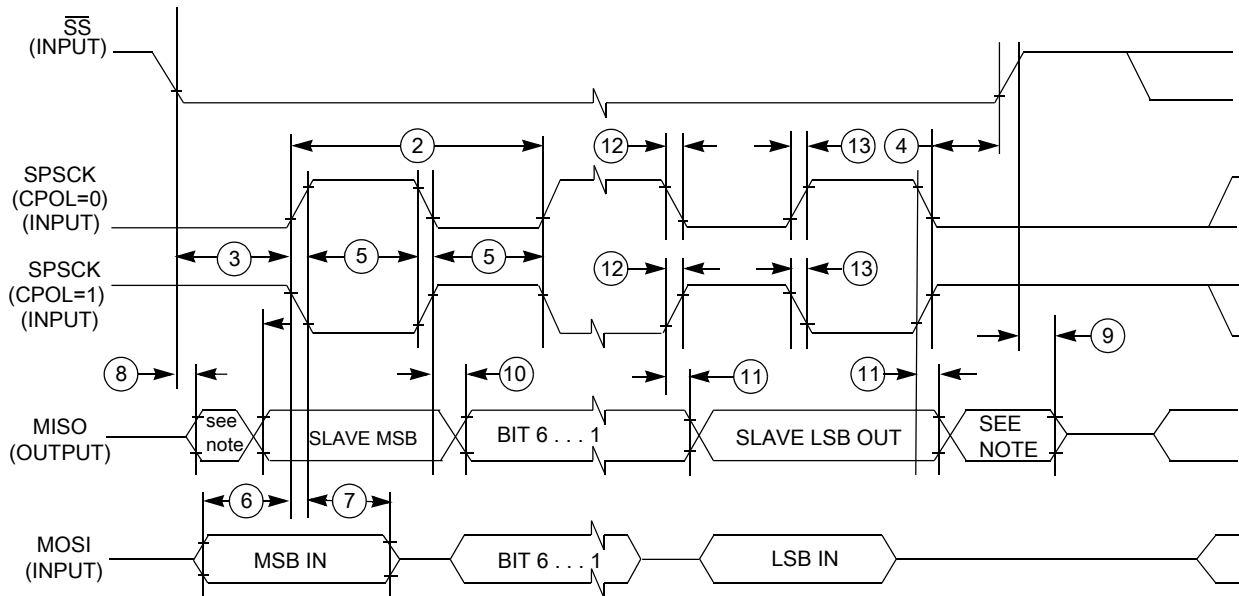


Figure 20. LPSPI slave mode timing (CPHA = 0)

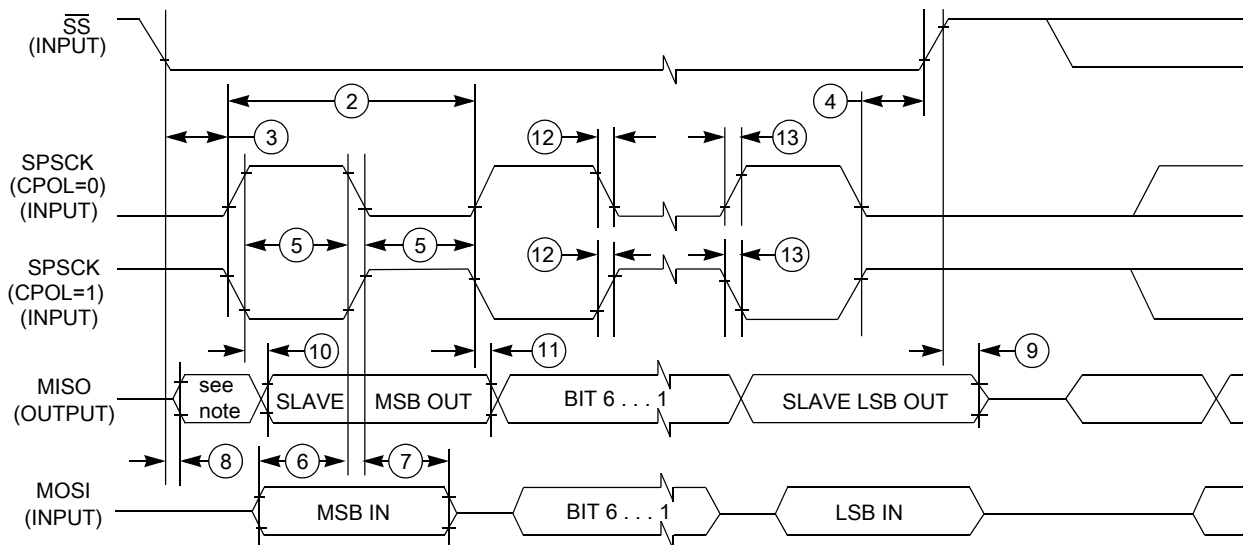


Figure 21. LPSPI slave mode timing (CPHA = 1)

### 6.5.3 LPI2C electrical specifications

See [General AC specifications](#) for LPI2C specifications.

For supported baud rate see section 'Chip-specific LPI2C information' of the *Reference Manual*.

## 6.5.4 FlexCAN electrical specifications

For supported baud rate, see section 'Protocol timing' of the *Reference Manual*.

## 6.5.5 SAI electrical specifications

The following table describes the SAI electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

**Table 30. Master mode timing specifications**

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S1	SAI_MCLK cycle time	40	—	ns
S2	SAI_MCLK pulse width high/low	45%	55%	MCLK period
S3	SAI_BCLK cycle time	80	—	ns
S4	SAI_BCLK pulse width high/low	45%	55%	BCLK period
S5	SAI_RXD input setup before SAI_BCLK	28	—	ns
S6	SAI_RXD input hold after SAI_BCLK	0	—	ns
S7	SAI_BCLK to SAI_TXD output valid	—	8	ns
S8	SAI_BCLK to SAI_TXD output invalid	-2	—	ns
S9	SAI_FS input setup before SAI_BCLK	28	—	ns
S10	SAI_FS input hold after SAI_BCLK	0	—	ns
S11	SAI_BCLK to SAI_FS output valid	—	8	ns
S12	SAI_BCLK to SAI_FS output invalid	-2	—	ns

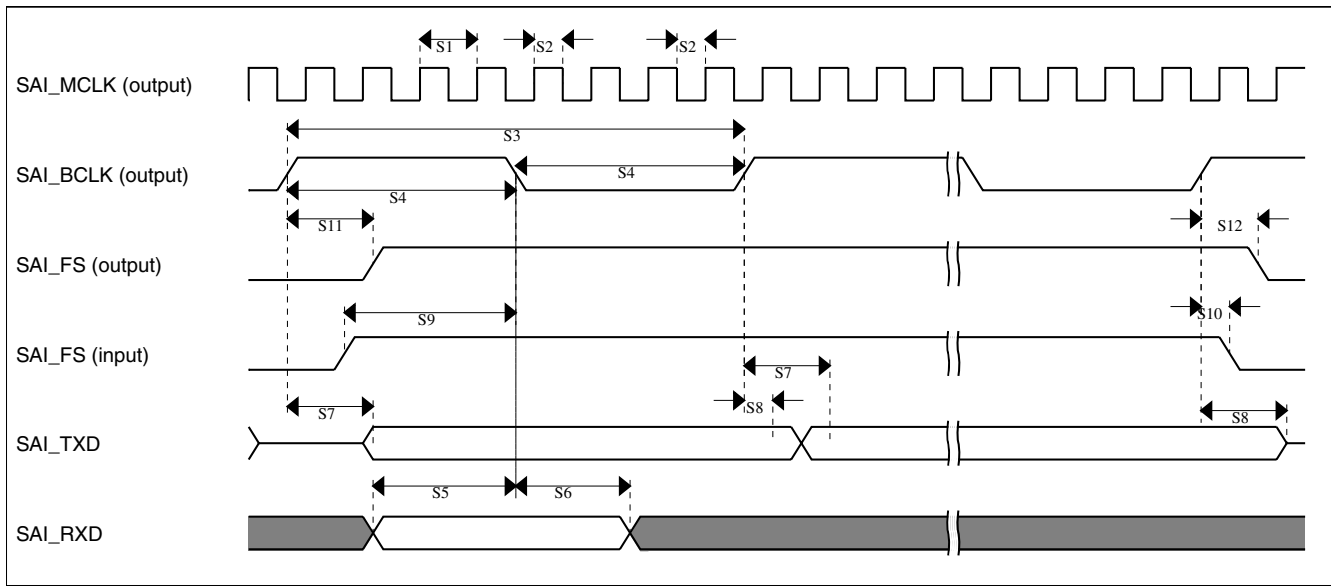


Figure 22. SAI Timing — Master modes

Table 31. Slave mode timing specifications

Symbol	Description	Min.	Max.	Unit
—	Operating voltage	2.97	3.6	V
S13	SAI_BCLK cycle time (input)	80	—	ns
S14 <sup>1</sup>	SAI_BCLK pulse width high/low (input)	45%	55%	BCLK period
S15	SAI_RXD input setup before SAI_BCLK	8	—	ns
S16	SAI_RXD input hold after SAI_BCLK	2	—	ns
S17	SAI_BCLK to SAI_TXD output valid	—	28	ns
S18	SAI_BCLK to SAI_TXD output invalid	0	—	ns
S19	SAI_FS input setup before SAI_BCLK	8	—	ns
S20	SAI_FS input hold after SAI_BCLK	2	—	ns
S21	SAI_BCLK to SAI_FS output valid	—	28	ns
S22	SAI_BCLK to SAI_FS output invalid	0	—	ns

1. The slave mode parameters (S15 - S22) assume 50% duty cycle on SAI\_BCLK input. Any change in SAI\_BCLK duty cycle input must be taken care during the board design or by the master timing.

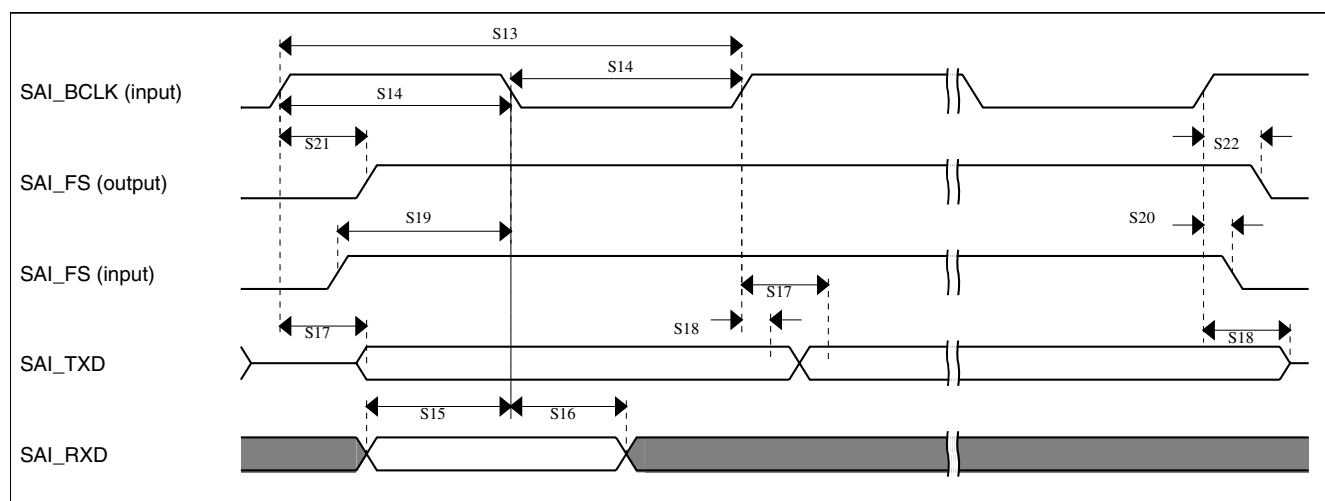


Figure 23. SAI Timing — Slave modes

## 6.5.6 Ethernet AC specifications

The following timing specs are defined at the chip I/O pin and must be translated appropriately to arrive at timing specs/constraints for the physical interface.

The following table describes the MII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN), the interface should be OFF.

Table 32. MII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RXCLK frequency	—	25	MHz
MII1	RXCLK pulse width high	35%	65%	RXCLK period
MII2	RXCLK pulse width low	35%	65%	RXCLK period
MII3	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
MII4	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
—	TXCLK frequency	—	25	MHz
MII5	TXCLK pulse width high	35%	65%	TXCLK period
MII6	TXCLK pulse width low	35%	65%	TXCLK period
MII7	TXCLK to TXD[3:0], TXEN, TXER invalid	2	—	ns
MII8	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns

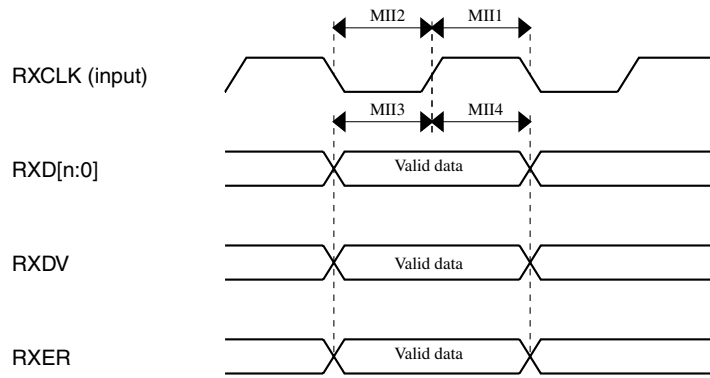


Figure 24. MII receive diagram

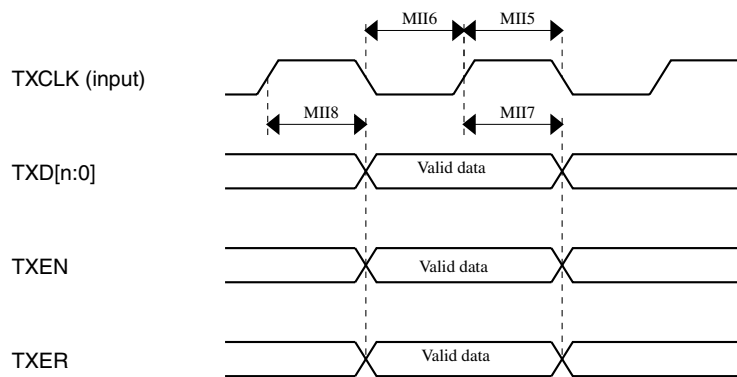


Figure 25. MII transmit signal diagram

The following table describes the RMII electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

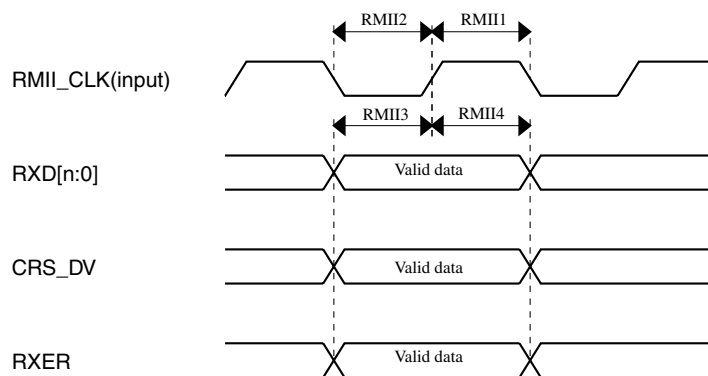
Table 33. RMII signal switching specifications

Symbol	Description	Min.	Max.	Unit
—	RMII input clock RMII_CLK Frequency	—	50	MHz
RMII1, RMII5	RMII_CLK pulse width high	35%	65%	RMII_CLK period
RMII2, RMII6	RMII_CLK pulse width low	35%	65%	RMII_CLK period
RMII3	RXD[1:0], CRS_DV, RXER to RMII_CLK setup	4	—	ns
RMII4	RMII_CLK to RXD[1:0], CRS_DV, RXER hold	2	—	ns

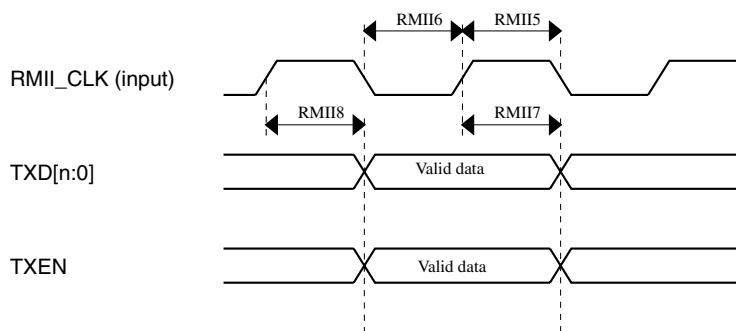
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**Table 33. RMI signal switching specifications (continued)**

Symbol	Description	Min.	Max.	Unit
RMI7	RMI_CLK to TXD[1:0], TXEN invalid	2	—	ns
RMI8	RMI_CLK to TXD[1:0], TXEN valid	—	15	ns



**Figure 26. RMI receive diagram**



**Figure 27. RMI transmit diagram**

The following table describes the MDIO electrical characteristics.

- Measurements are with maximum output load of 25 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- I/O operating voltage ranges from 2.97 V to 3.6 V
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.
- MDIO pin must have external Pull-up.

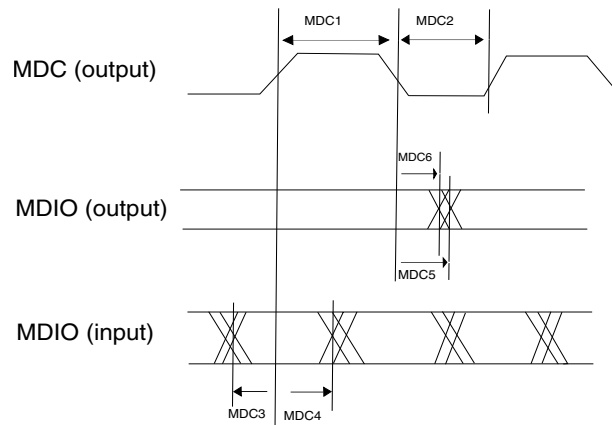
**Table 34. MDIO timing specifications**

Symbol	Description	Min.	Max.	Unit
—	MDC Clock Frequency	—	2.5	MHz

*Table continues on the next page...*

**Table 34. MDIO timing specifications (continued)**

Symbol	Description	Min.	Max.	Unit
MDC1	MDC pulse width high	40%	60%	MDC period
MDC2	MDC pulse width low	40%	60%	MDC period
MDC3	MDIO (input) to MDC rising edge setup	25	—	ns
MDC4	MDIO (input) to MDC rising edge hold	0	—	ns
MDC5	MDC falling edge to MDIO output valid (maximum propagation delay)	—	25	ns
MDC6	MDC falling edge to MDIO output invalid (minimum propagation delay)	-10	—	ns



**Figure 28. MII/RMII serial management channel timing diagram**

### 6.5.7 Clockout frequency

Maximum supported clock out frequency for this device is 20 MHz

## 6.6 Debug modules

### 6.6.1 SWD electrical specifications

**Table 35. SWD electrical specifications**

Symbol	Description	Run Mode						HSRUN Mode						VL	
		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO	Min.
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
S1	SWD_CLK frequency of operation	-	25	-	25	-	25	-	25	-	25	-	25	-	10
S2	SWD_CLK cycle period	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-	1/S1	-
S3	SWD_CLK clock pulse width	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5	S2/2 - 5	S2/2 + 5
S4	SWD_CLK rise and fall times	-	1	-	1	-	1	-	1	-	1	-	1	-	1
S9	SWD_DIO input data setup time to SWD_CLK rise	4	-	4	-	4	-	4	-	4	-	4	-	16	-
S10	SWD_DIO input data hold time after SWD_CLK rise	3	-	3	-	3	-	3	-	3	-	3	-	10	-
S11	SWD_CLK high to SWD_DIO data valid	-	28	-	38	-	38	-	28	-	28	-	38	-	70
S12	SWD_CLK high to SWD_DIO high-Z	-	28	-	38	-	38	-	28	-	28	-	38	-	70
S13	SWD_CLK high to SWD_DIO data invalid	0	-	0	-	0	-	0	-	0	-	0	-	0	-

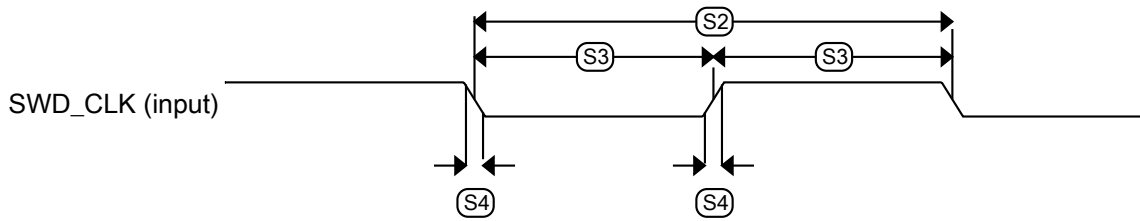


Figure 29. Serial wire clock input timing

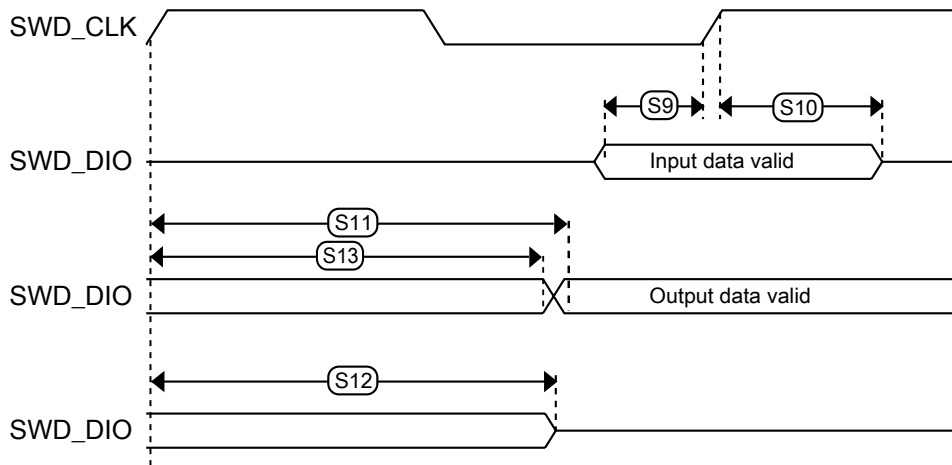


Figure 30. Serial wire data timing

### 6.6.2 Trace electrical specifications

The following table describes the Trace electrical characteristics.

- Measurements are with maximum output load of 50 pF, input transition of 1 ns and pad configured with fastest slew settings (DSE = 1'b1).
- While doing the mode transition (RUN -> HSRUN or HSRUN -> RUN ), the interface should be OFF.

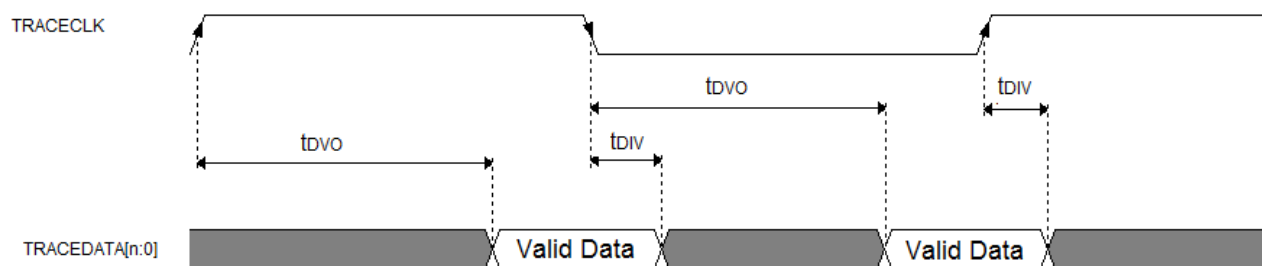
Table 36. Trace specifications

	Symbol	Description	RUN Mode			HSRUN Mode		VLPR Mode	Unit
			80	48	40	112	80		
—	Fsys	System frequency	80	48	40	112	80	4	MHz

Table continues on the next page...

**Table 36. Trace specifications (continued)**

	Symbol	Description	RUN Mode			HSRUN Mode		VLPR Mode	Unit
Trace on fast pads	$f_{TRACE}$	Max Trace frequency	80	48	40	74.667	80	4	MHz
	$t_{DVO}$	Data Output Valid	4	4	4	4	4	20	ns
	$t_{DIV}$	Data Output Invalid	-2	-2	-2	-2	-2	-10	ns
Trace on slow pads	$f_{TRACE}$	Max Trace frequency	22.86	24	20	22.4	22.86	4	MHz
	$t_{DVO}$	Data Output Valid	8	8	8	8	8	20	ns
	$t_{DIV}$	Data Output Invalid	-4	-4	-4	-4	-4	-10	ns



**Figure 31. TRACE CLKOUT specifications**

### 6.6.3 JTAG electrical specifications

**Table 37. JTAG electrical specifications**

Symbol	Description	Run Mode				HSRUN Mode				VLPR			
		5.0 V IO		3.3 V IO		5.0 V IO		3.3 V IO		5.0 V IO			
		Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.		
J1	TCLK frequency of operation	-	20	-	20	-	20	-	20	-	20	-	10
	Boundary Scan	-	20	-	20	-	20	-	20	-	20	-	10
J2	TCLK cycle period	1/J1	-	1/J1	-	1/J1	-	1/J1	-	1/J1	-	1/J1	-
J3	TCLK clock pulse width												
	Boundary Scan												
	JTAG												
J4	TCLK rise and fall times	J2/2 - 5	1	J2/2 - 5	1	J2/2 + 5	1	J2/2 - 5	J2/2 + 5	J2/2 - 5	1	J2/2 + 5	1
J5	Boundary scan input data setup time to TCLK rise	J2/2 - 5	5	J2/2 - 5	5	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	15	J2/2 + 5	-
J6	Boundary scan input data hold time after TCLK rise	J2/2 - 5	5	J2/2 - 5	5	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	8	J2/2 + 5	-
J7	TCLK low to boundary scan output data valid	J2/2 - 5	-	J2/2 - 5	28	J2/2 + 5	32	J2/2 - 5	J2/2 + 5	J2/2 - 5	-	J2/2 + 5	80
J8	TCLK low to boundary scan output data invalid	J2/2 - 5	0	J2/2 - 5	-	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	0	J2/2 + 5	-
J9	TCLK low to boundary scan output high-Z	J2/2 - 5	-	J2/2 - 5	28	J2/2 + 5	32	J2/2 - 5	J2/2 + 5	J2/2 - 5	-	J2/2 + 5	80
J10	TMS, TDI input data setup time to TCLK rise	J2/2 - 5	3	J2/2 - 5	-	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	3	J2/2 + 5	-
J11	TMS, TDI input data hold time after TCLK rise	J2/2 - 5	2	J2/2 - 5	-	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	2	J2/2 + 5	-
J12	TCLK low to TDO data valid	J2/2 - 5	-	J2/2 - 5	28	J2/2 + 5	32	J2/2 - 5	J2/2 + 5	J2/2 - 5	-	J2/2 + 5	80
J13	TCLK low to TDO data invalid	J2/2 - 5	0	J2/2 - 5	-	J2/2 + 5	-	J2/2 - 5	J2/2 + 5	J2/2 - 5	0	J2/2 + 5	-
J14	TCLK low to TDO high-Z	J2/2 - 5	-	J2/2 - 5	28	J2/2 + 5	32	J2/2 - 5	J2/2 + 5	J2/2 - 5	-	J2/2 + 5	80

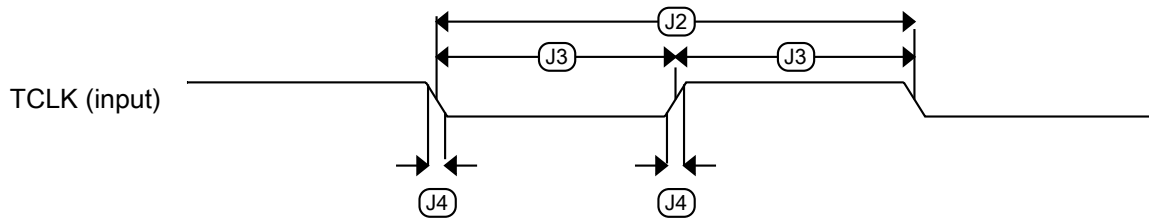


Figure 32. Test clock input timing

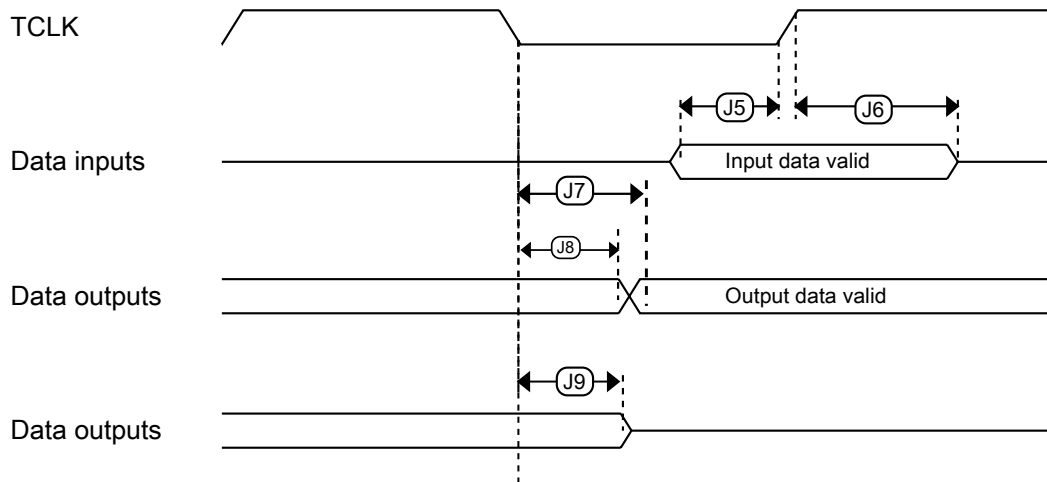


Figure 33. Boundary scan (JTAG) timing

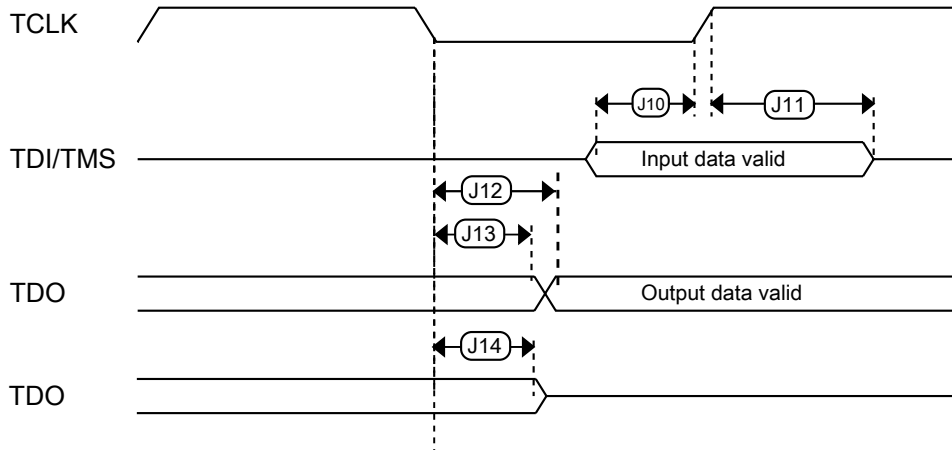


Figure 34. Test Access Port timing

## 7 Thermal attributes

### 7.1 Description

The tables in the following sections describe the thermal characteristics of the device.

#### NOTE

Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting side (board) temperature, ambient temperature, air flow, power dissipation or other components on the board, and board thermal resistance.

### 7.2 Thermal characteristics

**Table 38. Thermal characteristics for the 64/100/144/176-pin LQFP package**

Rating	Conditions	Symbol	Packages	Values		
				S32K11x	S32K142	S32K144
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1,2</sup>	Single layer board (1s)	R <sub>θJA</sub>	64	TBD	61	61
			100	TBD	53	52
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1</sup>	Two layer board (1s1p)	R <sub>θJA</sub>	64	TBD	45	45
			100	TBD	42	42
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1,2</sup>	Four layer board (2s2p)	R <sub>θJA</sub>	64	TBD	43	43
			100	TBD	40	40
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Ambient (@ 200 ft/min) <sup>1,3</sup>	Single layer board (1s)	R <sub>θJMA</sub>	64	TBD	49	49
			100	TBD	43	42
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Ambient (@ 200 ft/min) <sup>1</sup>	Two layer board (1s1p)	R <sub>θJMA</sub>	64	TBD	38	38
			100	TBD	35	35
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Ambient (@ 200 ft/min) <sup>1,3</sup>	Four layer board (2s2p)	R <sub>θJMA</sub>	64	TBD	36	36
			100	TBD	34	34
			144	TBD	NA	NA
			176	TBD	NA	NA
Thermal resistance, Junction to Board <sup>4</sup>	—	R <sub>θJB</sub>	64	TBD	25	25
			100	TBD	25	25
			144	TBD	NA	NA
			176	TBD	NA	NA

Table continues on the next page...

**Table 38. Thermal characteristics for the 64/100/144/176-pin LQFP package (continued)**

Rating	Conditions	Symbol	Packages	Values			
				S32K11x	S32K142	S32K144	S32K144
Thermal resistance, Junction to Case <sup>5</sup>	—	$R_{\theta JC}$	64	TBD	13	12	11
			100	TBD	13	12	11
			144	TBD	NA	NA	12
			176	TBD	NA	NA	NA
Thermal resistance, Junction to Package Top <sup>6</sup>	Natural Convection	$\psi_{JT}$	64	TBD	2	2	2
			100	TBD	2	2	2
			144	TBD	NA	NA	2
			176	TBD	NA	NA	NA

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 with natural convection for horizontally oriented board. Board meets JESD51-9 specification for 1s or 2s2p board.
3. Per JEDEC JESD51-6 with forced convection for horizontally oriented board. Board meets JESD51-9 specification for 1s or 2s2p board.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC. If letters are not available, the thermal characterization parameter is written as Psi-JT.

**Table 39. Thermal characteristics for the 100 MAPBGA package**

Rating	Conditions	Symbol	Values	
			S32K146	S32K144
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2</sup>	Single layer board (1s)	R <sub>θJA</sub>	57.2	61.0
Thermal resistance, Junction to Ambient (Natural Convection) <sup>1, 2, 3</sup>	Four layer board (2s2p)	R <sub>θJA</sub>	32.1	35.6
Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 2, 3</sup>	Single layer board (1s)	R <sub>θJMA</sub>	44.1	46.6
Thermal resistance, Junction to Ambient (@200 ft/min) <sup>1, 3</sup>	Two layer board (2s2p)	R <sub>θJMA</sub>	27.2	30.9
Thermal resistance, Junction to Board <sup>4</sup>	—	R <sub>θJB</sub>	15.3	18.9
Thermal resistance, Junction to Case <sup>5</sup>	—	R <sub>θJC</sub>	10.2	14.2
Thermal resistance, Junction to Package Top outside center <sup>6</sup>	—	ψ <sub>JT</sub>	0.2	0.4
Thermal resistance, Junction to Package Bottom outside center <sup>7</sup>	—	ψ <sub>JB</sub>	12.2	15.9

1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, flow, power dissipation of other components on the board, and board thermal resistance.
2. Per SEMI G38-87 and JEDEC JESD51-2 with the single layer board horizontal.
3. Per JEDEC JESD51-6 with the board horizontal.
4. Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC Method 1012.1. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.
7. Thermal characterization parameter indicating the temperature difference between package bottom center and the junction temperature per JEDEC Method 1012.1. When Greek letters are not available, the thermal characterization parameter is written as Psi-JB.

### 7.3 General notes for specifications at maximum junction temperature

An estimation of the chip junction temperature,  $T_J$ , can be obtained from this equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

- $T_A$  = ambient temperature for the package ( $^{\circ}\text{C}$ )
- $R_{\theta JA}$  = junction to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $P_D$  = power dissipation in the package ( $\text{W}$ )

The junction to ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. Unfortunately, there are two values in common usage: the value determined on a single layer board and the value obtained on a board with two planes. For packages such as the PBGA, these values can be different by a factor of two. Which value is closer to the application depends on the power dissipated by other components on the board. The value obtained on a single layer board is appropriate for the tightly packed printed circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated.

When a heat sink is used, the thermal resistance is expressed in the following equation as the sum of a junction-to-case thermal resistance and a case-to-ambient thermal resistance:

$$R_{\theta JA} = R_{\theta JC} + R_{\theta CA}$$

where:

- $R_{\theta JA}$  = junction to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $R_{\theta JC}$  = junction to case thermal resistance ( $^{\circ}\text{C}/\text{W}$ )
- $R_{\theta CA}$  = case to ambient thermal resistance ( $^{\circ}\text{C}/\text{W}$ )

$R_{\theta JC}$  is device related and cannot be influenced by the user. The user controls the thermal environment to change the case to ambient thermal resistance,  $R_{\theta CA}$ . For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed circuit board, or change the thermal dissipation on the printed circuit board surrounding the device.

To determine the junction temperature of the device in the application when heat sinks are not used, the Thermal Characterization Parameter ( $\Psi_{JT}$ ) can be used to determine the junction temperature with a measurement of the temperature at the top center of the package case using this equation:

$$T_J = T_T + (\Psi_{JT} \times P_D)$$

where:

- $T_T$  = thermocouple temperature on top of the package ( $^{\circ}\text{C}$ )
- $\Psi_{JT}$  = thermal characterization parameter ( $^{\circ}\text{C}/\text{W}$ )
- $P_D$  = power dissipation in the package (W)

The thermal characterization parameter is measured per JESD51-2 specification using a 40 gauge type T thermocouple epoxied to the top center of the package case. The thermocouple should be positioned so that the thermocouple junction rests on the package. A small amount of epoxy is placed over the thermocouple junction and over about 1 mm of wire extending from the junction. The thermocouple wire is placed flat against the package case to avoid measurement errors caused by cooling effects of the thermocouple wire.

## 8 Dimensions

### 8.1 Obtaining package dimensions

Package dimensions are provided in the package drawings.

To find a package drawing, go to <http://www.nxp.com> and perform a keyword search for the drawing's document number:

Package option	Document Number
32-pin QFN	SOT617-3 <sup>1</sup>
48-pin LQFP	98ASH00962A
64-pin LQFP	98ASS23234W
100-pin LQFP	98ASS23308W
100 MAP BGA	98ASA00802D
144-pin LQFP	98ASS23177W
176-pin LQFP	98ASS23479W

1. 5x5 mm package

## 9 Pinouts

### 9.1 Package pinouts and signal descriptions

For package pinouts and signal descriptions, refer to the Reference Manual.

## 10 Revision History

The following table provides a revision history for this document.

**Table 40. Revision History**

Rev. No.	Date	Substantial Changes
1	12 Aug 2016	Initial release
2	03 March 2017	<ul style="list-style-type: none"> <li>• Updated description of QSPI and Clock interfaces in Key Features section</li> <li>• Updated figure: <a href="#">High-level architecture diagram for the S32K1xx family</a></li> <li>• Updated figure: <a href="#">S32K1xx product series comparison</a></li> <li>• Added note in section <a href="#">Determining valid orderable parts</a></li> <li>• Updated figure: Ordering information</li> <li>• In table: <a href="#">Absolute maximum ratings</a> : <ul style="list-style-type: none"> <li>• Added footnote to <math>I_{INJPAD\_DC}</math></li> <li>• Updated min and max value of <math>I_{INJPAD\_DC}</math></li> <li>• Updated description, max and min values for <math>I_{INJSUM}</math></li> <li>• Updated <math>V_{IN\_TRANSIENT}</math></li> </ul> </li> <li>• In table: <a href="#">Voltage and current operating requirements</a> : <ul style="list-style-type: none"> <li>• Renamed <math>V_{SUP\_OFF}</math></li> <li>• Updated max value of <math>V_{DD\_OFF}</math></li> <li>• Removed <math>V_{INA}</math> and <math>V_{IN}</math></li> <li>• Added <math>V_{REFH}</math> and <math>V_{REFL}</math></li> <li>• Updated footnote "Typical conditions assumes <math>V_{DD} = V_{DDA} = V_{REFH} = 5</math> V ..."</li> <li>• Removed <math>I_{NJSUM\_AF}</math></li> </ul> </li> <li>• Updated footnotes in table <a href="#">Table 4</a></li> <li>• Updated section <a href="#">Power mode transition operating behaviors</a></li> <li>• In table: <a href="#">Power consumption</a> <ul style="list-style-type: none"> <li>• Added footnote "With PMC_REGSC[CLKBIASDIS] ... "</li> <li>• Updated conditions for VLPR</li> <li>• Removed Idd/MHz for S32K144</li> <li>• Updated numbers for S32K142 and S32K148</li> <li>• Removed use case footnotes</li> </ul> </li> <li>• In section <a href="#">Modes configuration</a> : <ul style="list-style-type: none"> <li>• Replaced table "Modes configuration" with spreadsheet attachment: 'S32K1xx_Power_Modes_Master_configuration_sheet'</li> </ul> </li> <li>• In table: <a href="#">DC electrical specifications at 3.3 V Range</a> : <ul style="list-style-type: none"> <li>• Added footnotes to <math>V_{ih}</math> Input Buffer High Voltage and <math>V_{ih}</math> Input Buffer Low Voltage</li> <li>• Added footnote to High drive port pins</li> </ul> </li> <li>• In table: <a href="#">DC electrical specifications at 5.0 V Range</a> :</li> </ul>

Table continues on the next page...

Table 40. Revision History

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• Added footnotes <math>V_{ih}</math> Input Buffer High Voltage and <math>V_{ih}</math> Input Buffer Low Voltage</li> <li>• Updated table: <a href="#">AC electrical specifications at 3.3 V range</a></li> <li>• Updated table: <a href="#">AC electrical specifications at 5 V range</a></li> <li>• In table: <a href="#">Standard input pin capacitance</a> <ul style="list-style-type: none"> <li>• Added footnote to Normal run mode (S32K14x series)</li> </ul> </li> <li>• Removed note from 1M ohms Feedback Resistor in figure <a href="#">Oscillator connections scheme</a></li> <li>• In table: <a href="#">External System Oscillator electrical specifications</a> <ul style="list-style-type: none"> <li>• Updated typical of <math>I_{DDOSC}</math> Supply current — low-gain mode (low-power mode) (HGO=0) 1 for 4 and 8 MHz</li> <li>• Removed rows for <math>I_{lk\_ext}</math> EXTAL/XTAL impedance High-frequency, low-gain mode (low-power mode) and high-frequency, high-gain mode and <math>V_{EXTAL}</math></li> <li>• Updated Typ. of <math>R_S</math> low-gain mode</li> <li>• Updated description of <math>R_F</math>, <math>R_S</math>, and <math>V_{PP}</math></li> <li>• Removed footnote from <math>R_F</math> Feedback resistor</li> <li>• Updated footnote for <math>C_1</math> <math>C_2</math> and <math>R_F</math></li> </ul> </li> <li>• In table: <a href="#">Table 16</a> <ul style="list-style-type: none"> <li>• Removed mention of high-frequency</li> <li>• Added HGO 0, 1 information</li> </ul> </li> <li>• In table: <a href="#">Fast internal RC Oscillator electrical specifications</a> <ul style="list-style-type: none"> <li>• Updated <math>F_{FIRC}</math></li> <li>• Updated description of <math>\Delta F</math></li> <li>• Updated typ and max values of <math>T_{JIT}</math> cycle-to-cycle jitter and <math>T_{JIT}</math> Long term jitter over 1000 cycles</li> <li>• Added footnotes to <math>T_{JIT}</math> cycle-to-cycle jitter and <math>T_{JIT}</math> Long term jitter over 1000 cycles</li> <li>• Updated naming convention of <math>I_{DDFIRC}</math> Supply current</li> <li>• Added footnote to <math>I_{DDFIRC}</math> Supply current</li> <li>• Added footnote to column Parameter</li> </ul> </li> <li>• In table: <a href="#">Slow internal RC oscillator (SIRC) electrical specifications</a> <ul style="list-style-type: none"> <li>• Removed <math>V_{DD}</math> Supply current in 2 MHz Mode</li> <li>• Removed footnote and updated description of <math>\Delta F</math></li> <li>• Updated footnote to <math>F_{SIRC}</math> and <math>I_{DSSIRC}</math></li> </ul> </li> <li>• In table: <a href="#">SPLL electrical specifications</a> <ul style="list-style-type: none"> <li>• Added row for <math>F_{SPLL\_REF}</math> PLL Reference</li> <li>• Updated naming convention throughout the table</li> <li>• Updated the max value of <math>T_{SPLL\_LOCK}</math> Lock detector detection time</li> </ul> </li> <li>• In table: <a href="#">Table 21</a> <ul style="list-style-type: none"> <li>• Added footnotes: <ul style="list-style-type: none"> <li>• All command times assumes ...</li> <li>• For all EEPROM Emulation terms ...</li> <li>• 'First time' EERAM writes after a POR ...</li> </ul> </li> <li>• Removed footnote 'Assumes 25 MHz or ...'</li> <li>• Updated Max of <math>t_{eevr32bers}</math></li> <li>• Added parameters <math>t_{quickwr}</math> and <math>t_{quickwrCinup}</math></li> </ul> </li> <li>• In table: <a href="#">Table 22</a> <ul style="list-style-type: none"> <li>• Removed Typ. values for all parameters</li> <li>• Removed footnote 'Typical values represent ...'</li> <li>• Added footnote 'Any other EEE driver usage ...'</li> </ul> </li> <li>• Updated <a href="#">QuadSPI AC specifications</a></li> <li>• Removed topic: Reliability, Safety and Security modules</li> <li>• In table: <a href="#">12-bit ADC operating conditions</a> <ul style="list-style-type: none"> <li>• Updated <math>V_{DDA}</math></li> </ul> </li> </ul>

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Table 40. Revision History (continued)

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• Updated values for <math>V_{REFH}</math> and <math>V_{REFL}</math> to add reference to the section "voltage and current operating requirements" for Min and Max values</li> <li>• Updated footnote to Typ.</li> <li>• Removed footnote from RAS Analog source resistance</li> <li>• Updated figure: ADC input impedance equivalency diagram</li> <li>• In table: <a href="#">12-bit ADC characteristics (2.7 V to 3 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Removed rows for <math>V_{TEMP\_S}</math> and <math>V_{TEMP25}</math></li> <li>• Updated footnote to Typ.</li> </ul> </li> <li>• In table: <a href="#">12-bit ADC characteristics (3 V to 5.5 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Removed rows for <math>V_{TEMP\_S}</math> and <math>V_{TEMP25}</math></li> <li>• Removed number for TUE</li> <li>• Updated footnote to Typ.</li> </ul> </li> <li>• In table: <a href="#">Comparator with 8-bit DAC electrical specifications</a> <ul style="list-style-type: none"> <li>• Updated Typ. of <math>I_{DDL5}</math> Supply current, Low-speed mode</li> <li>• Updated Typ. of <math>t_{DL5B}</math> Propagation delay, Low-speed mode</li> <li>• Updated Typ. of <math>t_{DH5S}</math> Propagation delay, High-speed mode</li> <li>• Updated <math>t_{DL5S}</math> Propagation delay</li> <li>• Added row for <math>t_{DDAC}</math> Initialization and switching settling time</li> <li>• Updated footnote</li> </ul> </li> <li>• Updated section <a href="#">LPSPI electrical specifications</a></li> <li>• Added section: <a href="#">SAI electrical specifications</a></li> <li>• Updated section: <a href="#">Ethernet AC specifications</a></li> <li>• Added section: <a href="#">Clockout frequency</a></li> <li>• Added section: <a href="#">Trace electrical specifications</a></li> <li>• Updated table: <a href="#">Table 38</a> : Updated numbers for S32K142 and S32K148</li> <li>• Updated table: <a href="#">Table 39</a> : Updated numbers for S32K148</li> <li>• Updated Document number for 32-pin QFN in topic <a href="#">Obtaining package dimensions</a></li> </ul>
3	14 March 2017	<ul style="list-style-type: none"> <li>• In <a href="#">Table 2</a> <ul style="list-style-type: none"> <li>• Updated min. value of <math>V_{DD\_OFF}</math></li> <li>• Added parameter <math>I_{INJ\_SUM\_AF}</math></li> </ul> </li> <li>• Updated <a href="#">Power mode transition operating behaviors</a></li> <li>• Updated <a href="#">Power consumption</a></li> <li>• Updated footnote to <math>T_{SPLL\_LOCK}</math> in <a href="#">SPLL electrical specifications</a></li> <li>• In <a href="#">12-bit ADC electrical characteristics</a> <ul style="list-style-type: none"> <li>• Updated table: <a href="#">12-bit ADC characteristics (2.7 V to 3 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Added typ. value to <math>I_{DDA\_ADC}</math>, TUE, DNL, and INL</li> <li>• Added min. value to SMPLTS</li> <li>• Removed footnote 'All the parameters in this table ... '</li> </ul> </li> <li>• Updated table: <a href="#">12-bit ADC characteristics (3 V to 5.5 V)</a> (<math>V_{REFH} = V_{DDA}</math>, <math>V_{REFL} = V_{SS}</math>) <ul style="list-style-type: none"> <li>• Added typ. value to <math>I_{DDA\_ADC}</math></li> <li>• Removed footnote 'All the parameters in this table ... '</li> </ul> </li> </ul> </li> <li>• In <a href="#">Table 21</a> updated Max. value of <math>t_{Vfykey}</math> to 33 <math>\mu</math>s</li> </ul>
4	02 June 2017	<ul style="list-style-type: none"> <li>• In section: <a href="#">Block diagram</a>, added block diagram for S32K11x series.</li> <li>• Updated figure: <a href="#">S32K1xx product series comparison</a>.</li> <li>• In section: <a href="#">Determining valid orderable parts</a> , added reference to attachment <a href="#">S32K_Part_Numbers.xlsx</a>.</li> <li>• In section: <a href="#">Ordering information</a> <ul style="list-style-type: none"> <li>• Updated figure: Ordering information.</li> </ul> </li> <li>• In <a href="#">Table 1</a>,</li> </ul>

Table 40. Revision History

Rev. No.	Date	Substantial Changes
		<ul style="list-style-type: none"> <li>• Updated note 'All the limits defined ...'</li> <li>• Updated parameter 'I<sub>INJPAD_DC_ABS</sub>', 'V<sub>IN_DC</sub>', I<sub>INJSUM_DC_ABS</sub>.</li> <li>• In <a href="#">Table 2</a>, <ul style="list-style-type: none"> <li>• Updated parameter I<sub>INJPAD_DC_OP</sub> and I<sub>INJSUM_DC_OP</sub>.</li> </ul> </li> <li>• In <a href="#">Table 5</a>, updated TBDs for V<sub>LVR_HYST</sub>, V<sub>LVD_HYST</sub>, and V<sub>LVW_HYST</sub></li> <li>• In <a href="#">Table 6</a>, <ul style="list-style-type: none"> <li>• Added VLPR → VLPS</li> <li>• Added VLPS → VLPR</li> <li>• Updated TBDs for VLPS → Asynchronous DMA Wakeup, STOP1 → Asynchronous DMA Wakeup, and STOP2 → Asynchronous DMA Wakeup</li> </ul> </li> <li>• In <a href="#">Table 7</a>, updated the specifications for S32K144.</li> <li>• Updated the attachment <i>S32K1xx_Power_Modes_Configuration.xlsx</i>.</li> <li>• In <a href="#">Table 13</a>, removed C<sub>IN_A</sub>.</li> <li>• In <a href="#">Table 15</a>, <ul style="list-style-type: none"> <li>• Updated specificatins for g<sub>mXOSC</sub>.</li> <li>• Removed I<sub>DDOSC</sub></li> </ul> </li> <li>• In <a href="#">Table 17</a>, <ul style="list-style-type: none"> <li>• Added parameter ΔF125.</li> <li>• Removed I<sub>DDFIRC</sub></li> </ul> </li> <li>• In <a href="#">Table 18</a>, <ul style="list-style-type: none"> <li>• Added parameter ΔF125.</li> <li>• Removed I<sub>DDSIRC</sub></li> </ul> </li> <li>• In <a href="#">Table 19</a>, removed I<sub>LPO</sub></li> <li>• Updated section: <a href="#">Flash memory module (FTFC) electrical specifications</a></li> <li>• In section: <a href="#">12-bit ADC operating conditions</a>, <ul style="list-style-type: none"> <li>• Updated TBDs for I<sub>DDA_ADC</sub> and TUE in <a href="#">Table 25</a></li> <li>• Updated TBDs for I<sub>DDA_ADC</sub> and TUE in <a href="#">Table 26</a></li> </ul> </li> <li>• In section: <a href="#">QuadSPI AC specifications</a>, updated figure 'QuadSPI output timing (HyperRAM mode) diagram'.</li> <li>• In section: <a href="#">12-bit ADC operating conditions</a>, updated <a href="#">Table 24</a>.</li> <li>• In section: <a href="#">CMP with 8-bit DAC electrical specifications</a>, added note 'For comparator IN signals adjacent ...'</li> <li>• In table: <a href="#">Table 29</a>, minor update in footnote 6.</li> <li>• In table: <a href="#">Table 38</a>, updated specifications for S32K146.</li> </ul>

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